

PULSED POWER SYSTEM

脈衝功率系統



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2023 Fall Semester

Tuesday 9:10-12:00

Lecture 8

<http://capst.ncku.edu.tw/PGS/index.php/teaching/>

Online courses:

<https://nckucc.webex.com/nckucc/j.php?MTID=md577c3633c5970f80cbc9e821927e016>

Reference



- **Foundations of pulsed power technology, by Jane Lehr & Pralhad Ron**
- **Pulsed power systems, by H. Bluhm**
- **Pulsed power, by Gennady A. Mesyats**
- **J. C. Martin on pulsed power, edited by T. H. Martin, A. H. Guenther, and M. Kristiansen**
- **Pulse power formulary, by Richard J. Adler**

- **Circuit analysis, by Cunningham and Stuller**

Outlines



- **Switches**
 - **Closing switches: the switching process is associated with voltage breakdown across an initially insulant element.**
 - **Opening switches: the switching process is associated with a sudden growth of its impedence.**
- **Pulse-forming lines**
 - Blumlein line
 - Pulse-forming network
 - Pulse compressor
- **Pulse transmission and transformation**

Outlines

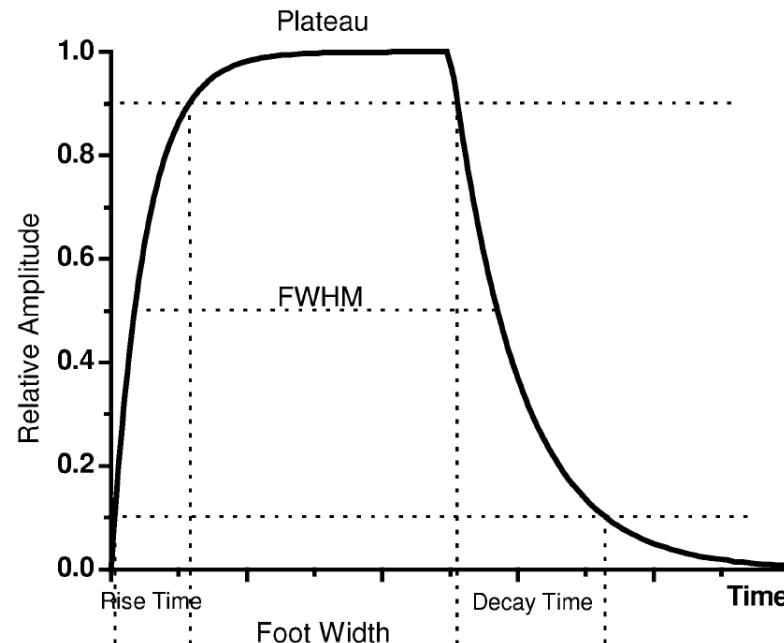


- **Switches**
 - **Closing switches**
 - Opening switches
- Pulse-forming lines
 - Blumlein line
 - Pulse-forming network
 - Pulse compressor
- Pulse transmission and transformation
 - Self-magnetic insulation
 - Pulse transformer
 - Voltage multiplier
 - H-bridge pulse generator
 - Fast high-voltage pulse generator

Switches



- High-power switching systems are the connecting elements between the storage device and the load.
- Characteristics of the generator output pulse that is strongly dependent on the properties of the switches:
 - Rise time.
 - Shape.
 - Amplitude.



Closing switches



- **The switching process is associated with voltage breakdown across an initially insulant element.**
 - **Automatically.**
 - **Externally supplied trigger pulse.**

Gas switches (Spark-gap switches)

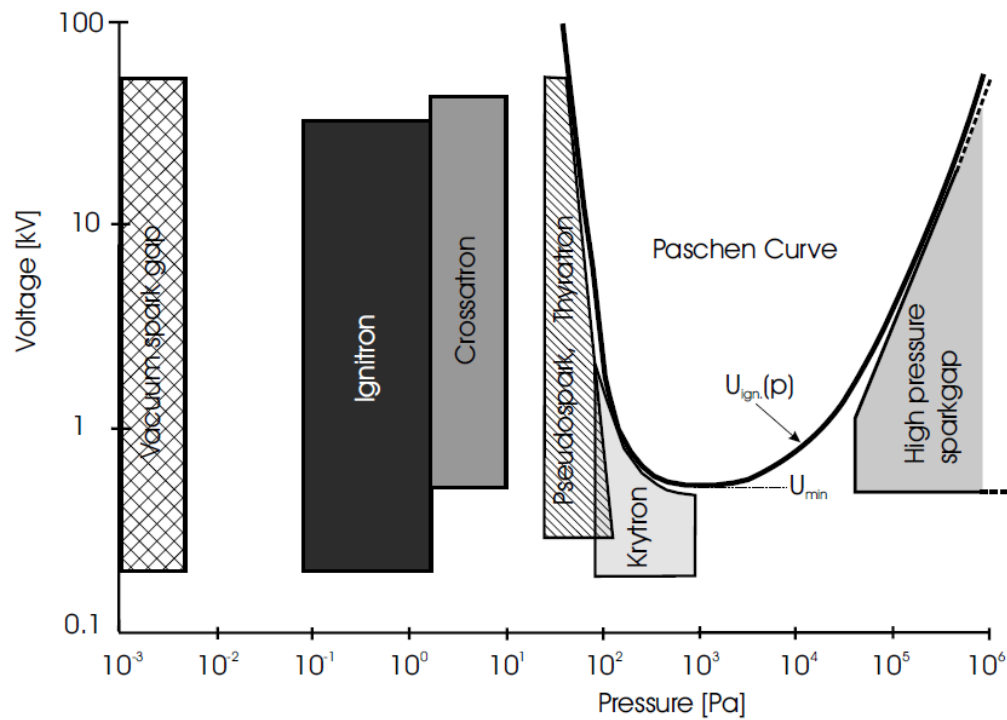


- **Advantage of a gas switch:**
 - **Commonly applied in high-power pulse generators.**
 - **Easy to use.**
 - **Capable of handling large currents.**
 - **Capable of handling large charges.**
 - **Can be triggered precisely.**
- **Many applications require a precisely controlled initiation of the voltage breakdown.**
- **The trigger method has a big influence on the ignition delay and its variance (jitter).**

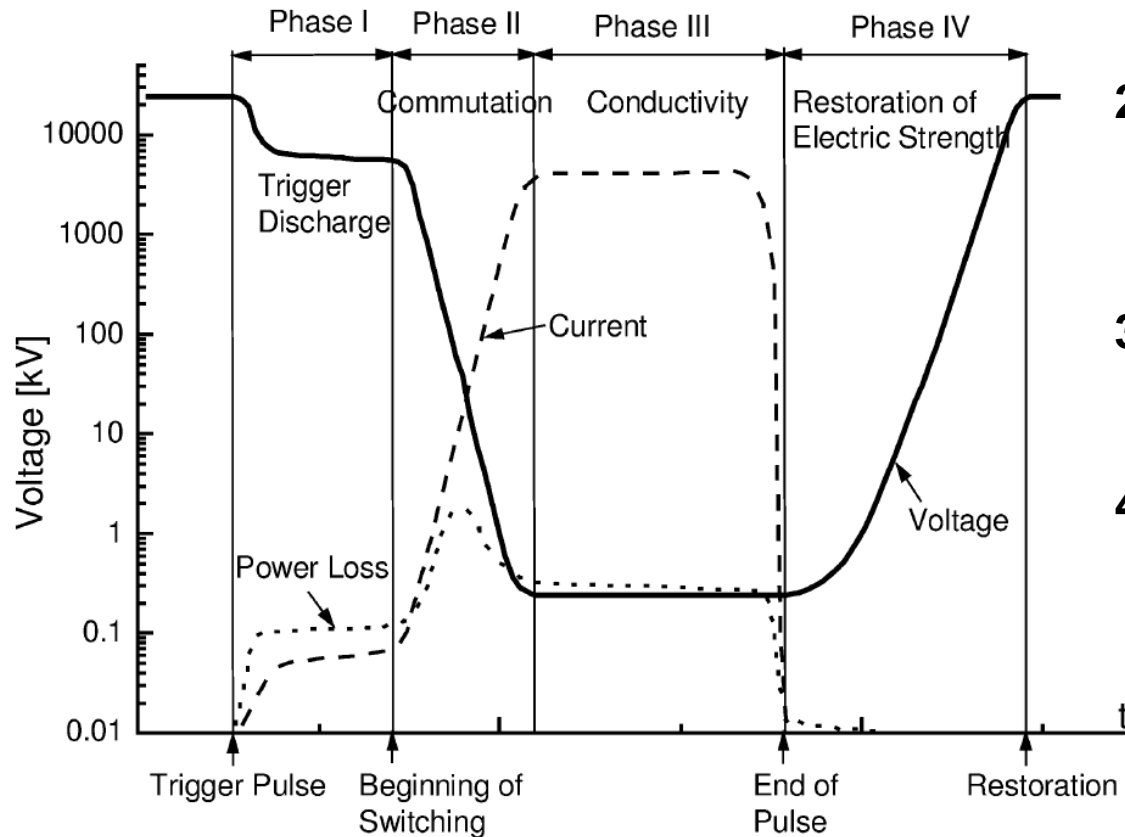
Different closing switches operate in different pressure



84 4 Switches



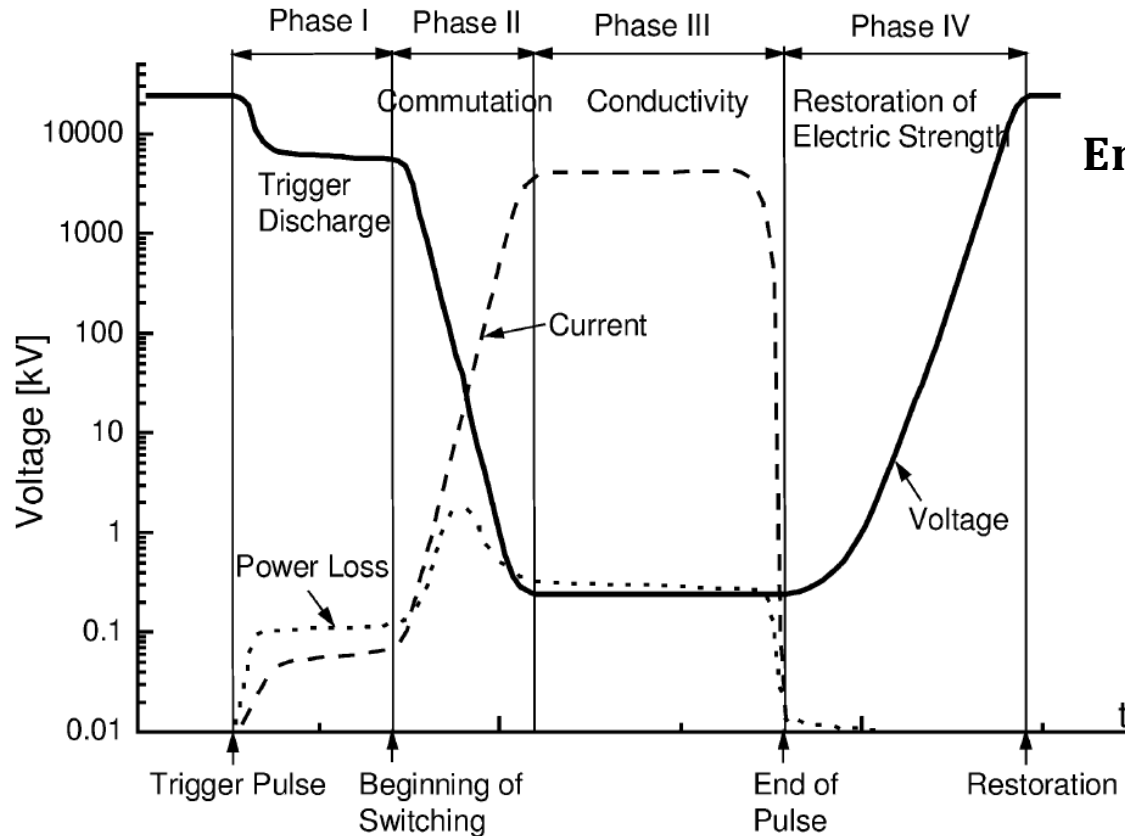
All switching systems operates in 4 phases



1. **Trigger phase: build-up of a trigger discharge.**
2. **Transition/commutation phase: transition from high to low switch impedance.**
3. **Stationary/conductivity phase: constant conductivity.**
4. **Recovery/restoration phase: restoration of the previous electric strength.**

Fig. 4.2. Evolution of voltage, current, and power loss in a gas-filled switching system

Cooling is needed to remove the energy loss for the breakdown.



$$\begin{aligned}
 \text{Eng} &= \int_0^{\tau_S} U(t)I(t) dt \\
 &\approx \int_0^{\tau_S} U_M \left(1 - \frac{t}{\tau_S}\right) I_M \frac{t}{\tau_S} dt \\
 &= U_M I_M \int_0^{\tau_S} \left(1 - \frac{t}{\tau_S}\right) \frac{t}{\tau_S} dt \\
 &= \frac{U_M I_M \tau_S}{6} \approx 0.2 U_M I_M \tau_r
 \end{aligned}$$

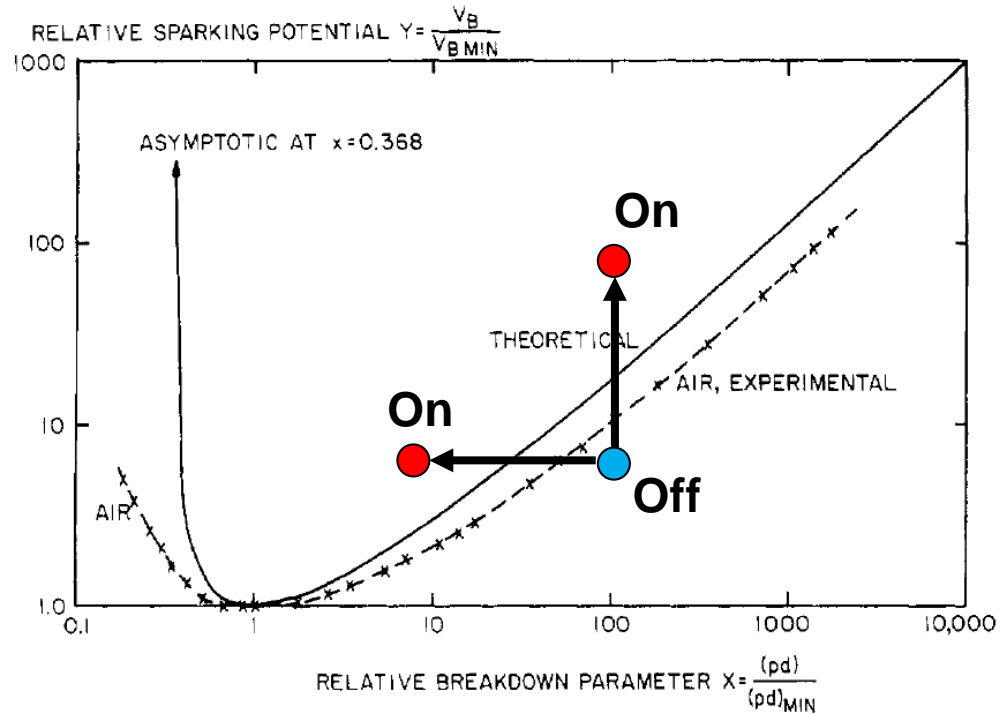
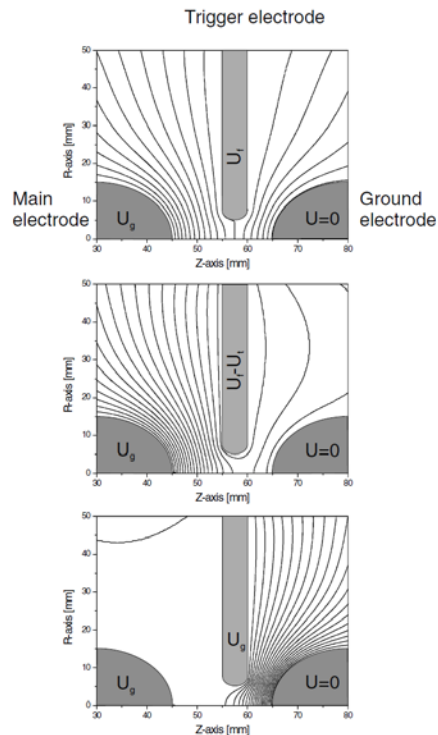
Fig. 4.2. Evolution of voltage, current, and power loss in a gas-filled switching system

- τ_S : switching time
- τ_r : pulse rise time ($\tau_r \approx 0.8 \tau_S$)
- U_M/I_M : maximum voltage/current

Gas-filled spark gaps



- Breakdown due to:
 - Breakdown voltage has been exceeded.
 - Breakdown strength has been reduced by certain events (UV radiation, plasma diffusion, etc.)

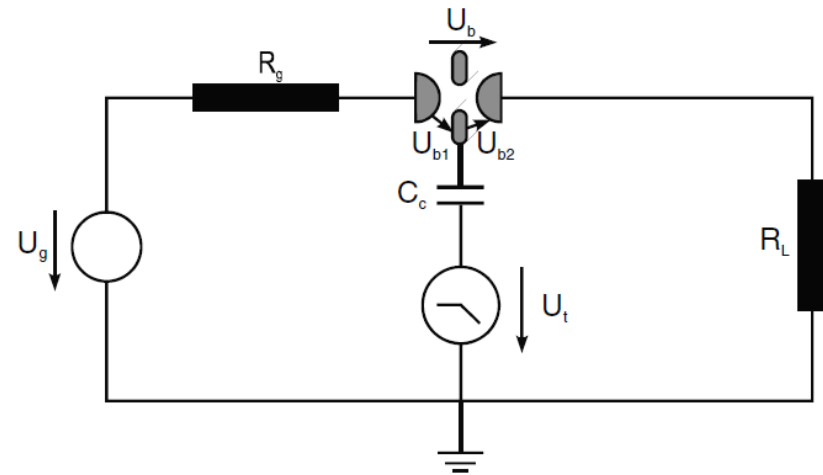
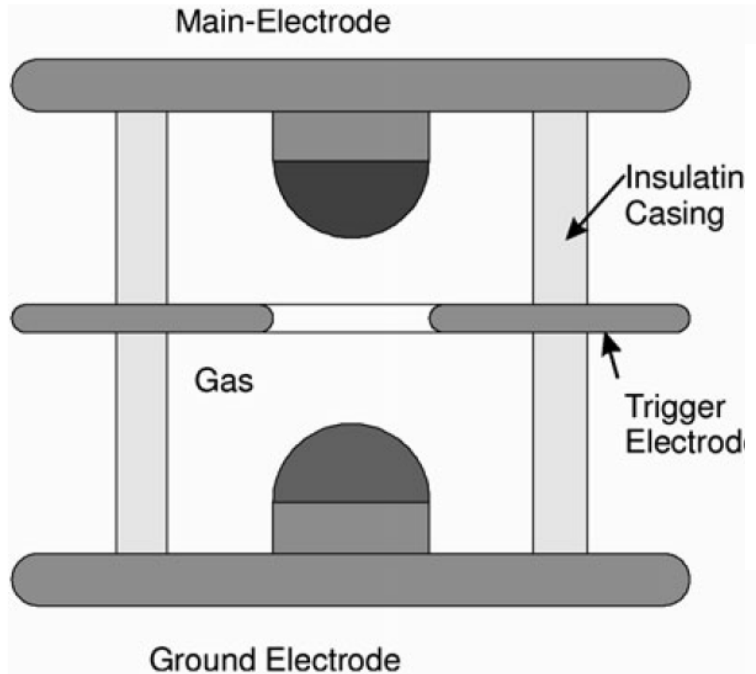


Gas-filled spark gaps



- **Important parameters:**
 - **Self-breakdown / hold-off voltage U_b .**
 - **Variance of U_b : determines the probability of breakdown.**
 - **Operation range: range of voltage**
 - **Held off with sufficiently low pre-breakdown possibility.**
 - **Reliably triggered.**
 - **Jitter.**
 - **Switching time t_s : decay of the impedance (resistance and inductance).**
 - **Pre-breakdown inductance and capacitance.**
 - **Repetition rate capability.**
 - **Lifetime and cost.**
- **Triggering can be achieved by (1) a High-voltage pulse; (2) a laser pulse.**

Spark-gap switch



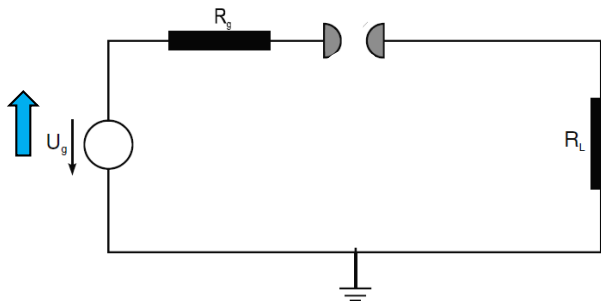
- U_g : generator voltage.
- U_t : triggering voltage.
- R_g : generator impedance.
- R_L : load impedance.
- U_b : breakdown voltage.
- U_{b1}/U_{b2} : breakdown voltage of the partial gaps.
- C_c : coupling capacitor.

Spark-gap switch

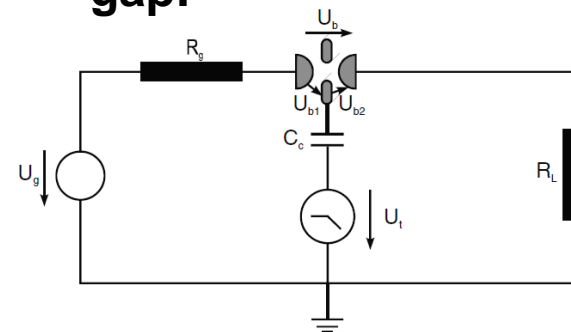


- Longitudinal overvoltage triggering – if the voltage amplitude of the trigger pulse added to the applied operating voltage is sufficient to breakdown a partial gap.
- Ignition of the 2nd partial gap occurs if its breakdown voltage is less than the operating voltage.
- C_c is used to decouple the trigger source from the generator.
- $C_c \gg C_{b1} \Rightarrow U_t(t = 0) = U_g \frac{C_{b1}}{C_c + C_{b1}} \approx 0$

- Longitudinal overvoltage triggering:



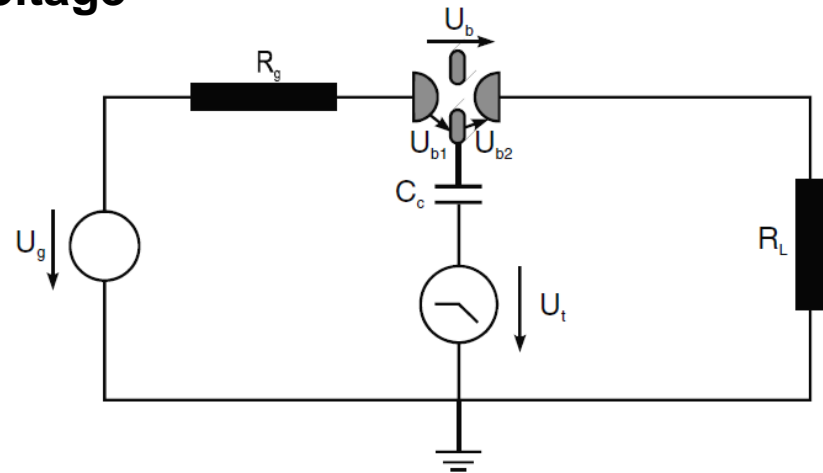
- Ignition of the 2nd partial gap:



Spark-gap switch



$U_g + |U_t| > U_{b1}$ (longitudinal overvoltage triggering)
 $|U_t| < U_{b2}$ (U_t doesn't cause breakdown @ gap2)
 $U_g > U_{b2}$
 $U_g \geq U_{b2} \Rightarrow U_{g,min} = U_{b2}$
 $|U_{t,max}| \leq U_{b2} \Rightarrow |U_{t,max}| = U_{b2}$
 $U_{g,min} + |U_{t,max}| = 2U_{b2} > U_{b1} \Rightarrow U_{b2} = \frac{1}{2} U_{b1}$



- For a symmetric spark gap configuration, the trigger electrode should be positioned at 2/3 of the gap spacing from the main electrode.

$$U_g < U_{b1} = 2U_{b2}$$

$$U_{b2} < U_g < U_{b2} \quad \text{or} \quad \frac{1}{3} U_b < U_g < \frac{2}{3} U_b$$

Three-electrode trigger set-up



$$\frac{2}{3}U_g < U_{b1}$$

$$U_g > U_{b2}$$

$$U_g + |U_t| > U_{b1}$$

$$|U_t| < U_{b2}$$

$$U_g \geq U_{b2} \Rightarrow U_{g,\min} = U_{b2}$$

$$|U_{t,\max}| \leq U_{b2} \Rightarrow |U_{t,\max}| = U_{b2}$$

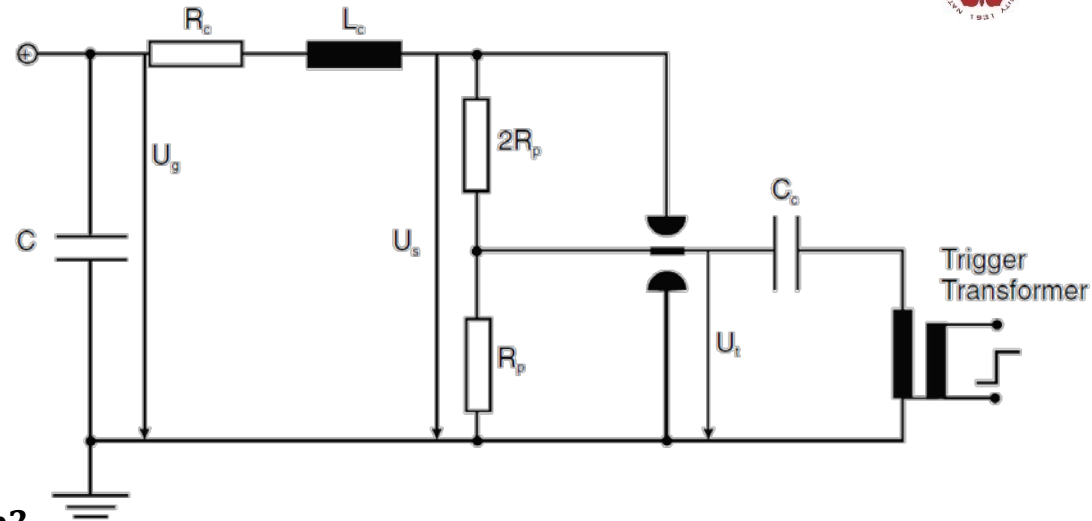
$$U_{g,\min} + |U_{t,\max}| = 2U_{b2} > U_{b1} \Rightarrow U_{b2} = \frac{1}{2}U_{b1}$$

$$\frac{2}{3}U_g < U_{b1} = 2U_{b2} \Rightarrow \frac{1}{3}U_g < U_{b2} \text{ or } U_g < 3U_{b2}$$

$$U_{b2} < U_g < 3U_{b2}$$

$$U_b = U_{b1} + U_{b2} = 2U_{b2} + U_{b2} = 3U_{b2}$$

$$\text{or } \frac{1}{3}U_b < U_g < U_b$$



Potential distribution of a spark-gap

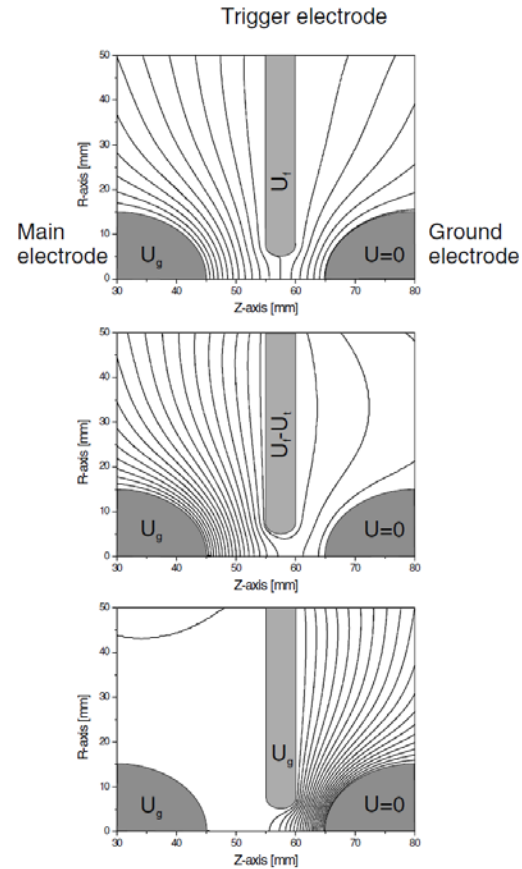
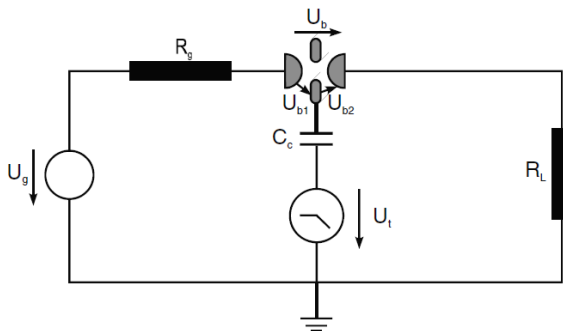
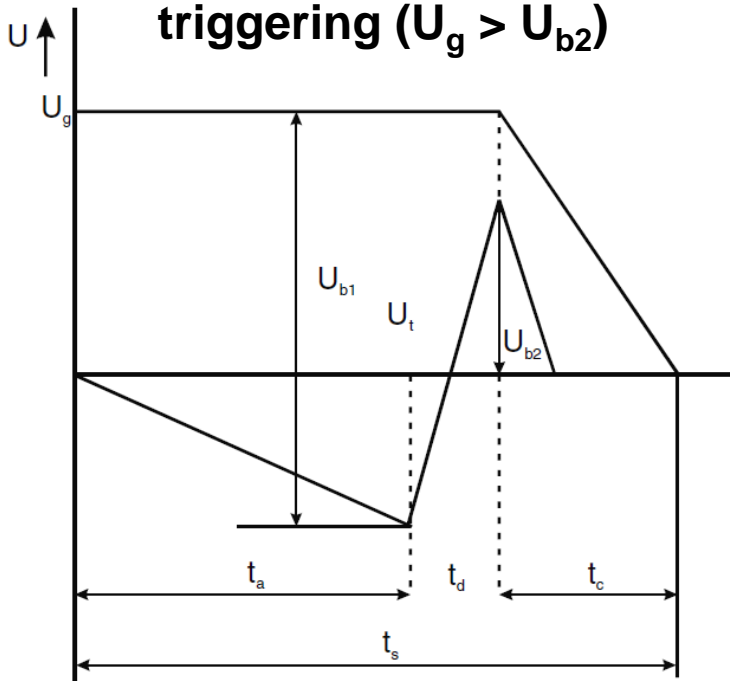


Fig. 4.6. Potential distribution in a three-electrode spark gap switch, before ignition (*top*), after application of a trigger signal (*centre*), and after breakdown of the first gap (*bottom*)

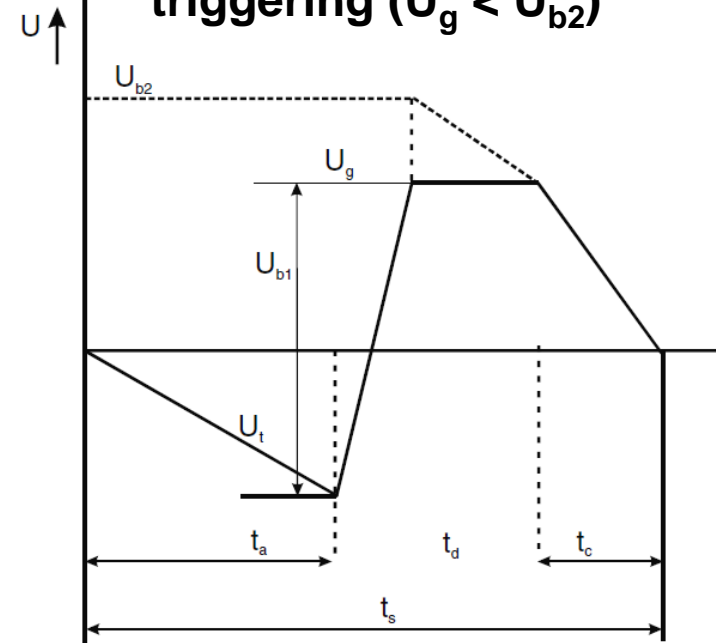
Longitudinal triggering



- Longitudinal-overvoltage triggering ($U_g > U_{b2}$)



- Longitudinal-plasma triggering ($U_g < U_{b2}$)

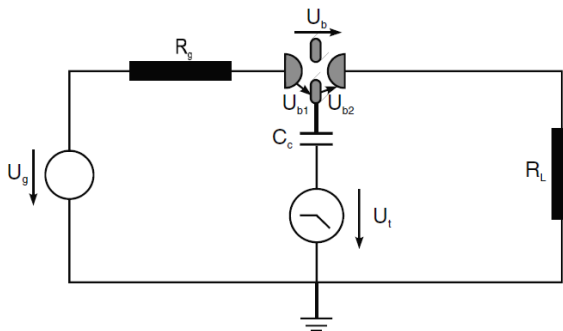
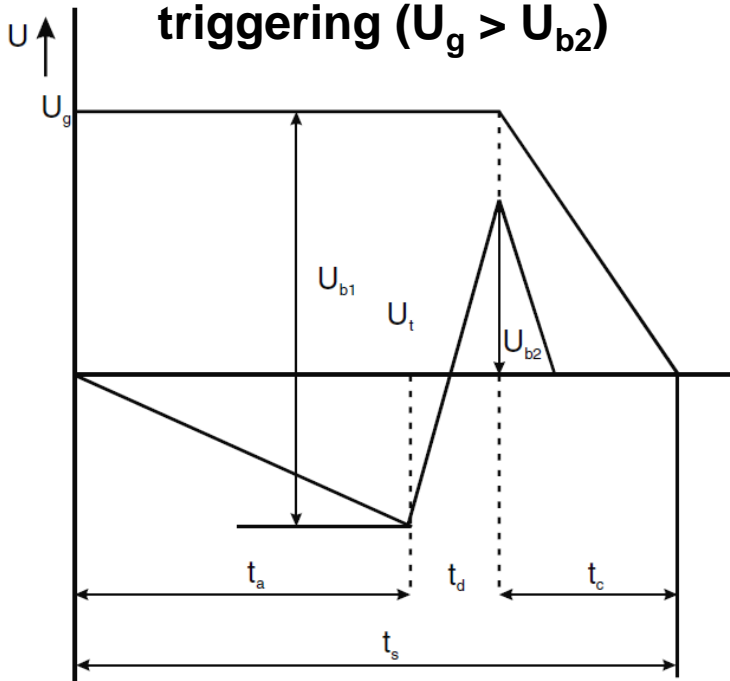


- t_a : trigger actuating time.
- t_d : switching delay.
- t_c : commutation time.
- t_s : switching time.

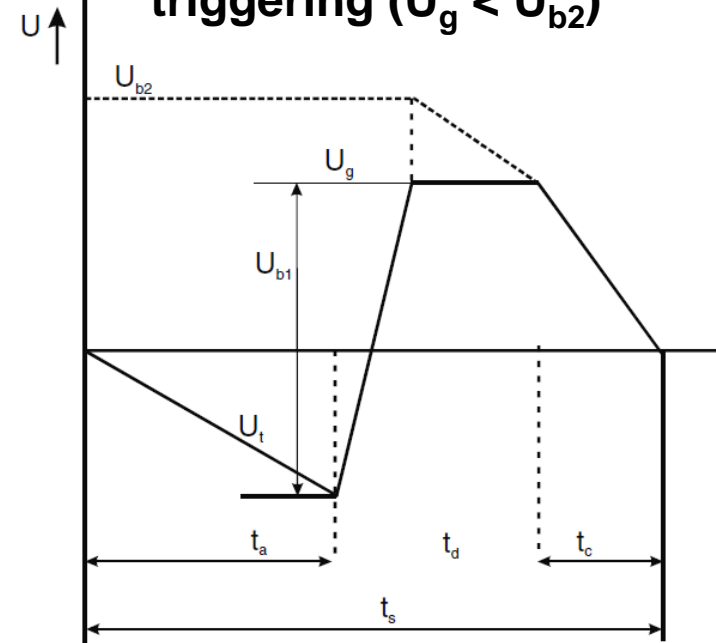
Longitudinal triggering



- Longitudinal-overvoltage triggering ($U_g > U_{b2}$)



- Longitudinal-plasma triggering ($U_g < U_{b2}$)

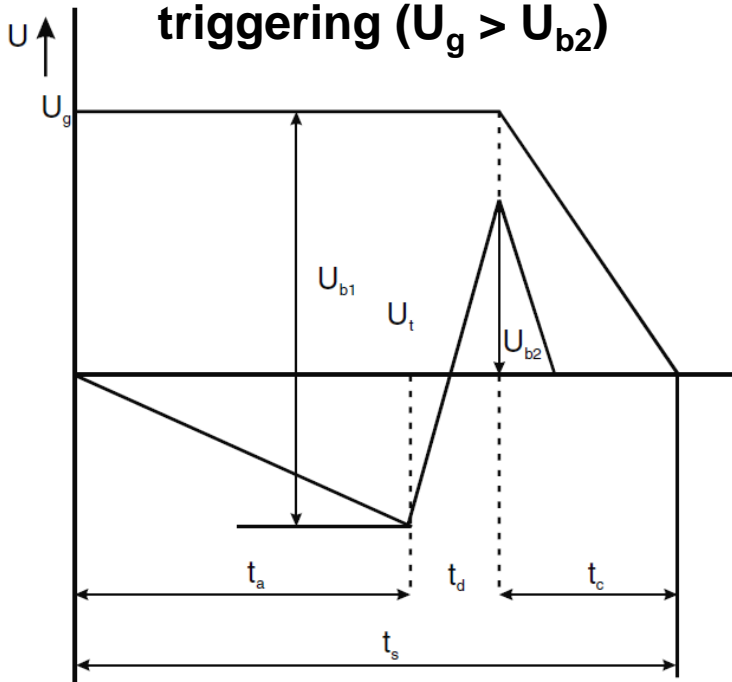


- **2nd gap can fire only if its breakdown strength is continuous reduced by UV radiation from the spark channel plasma of the 1st gap. => much larger switch delay time.**

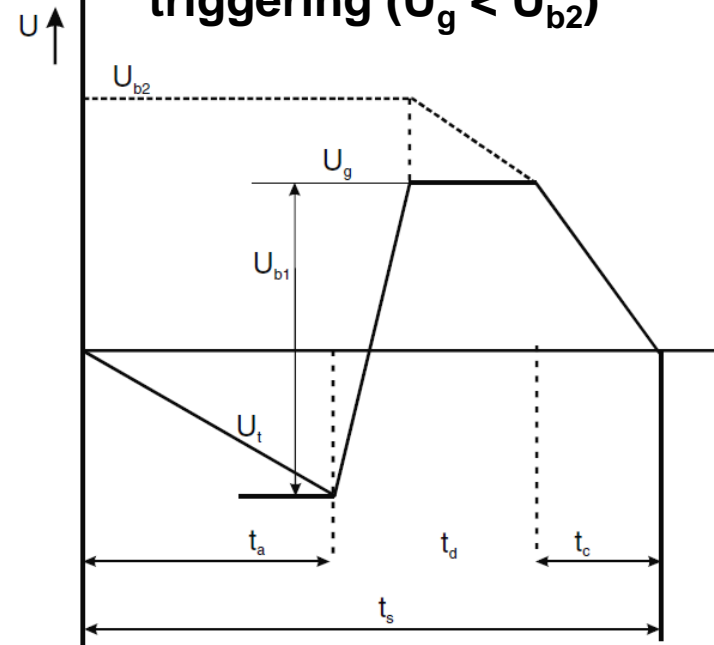
Longitudinal triggering



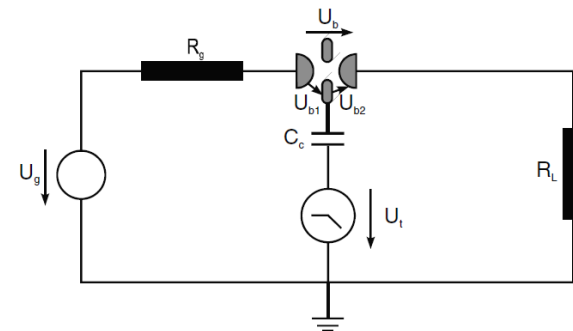
- Longitudinal-overvoltage triggering ($U_g > U_{b2}$)



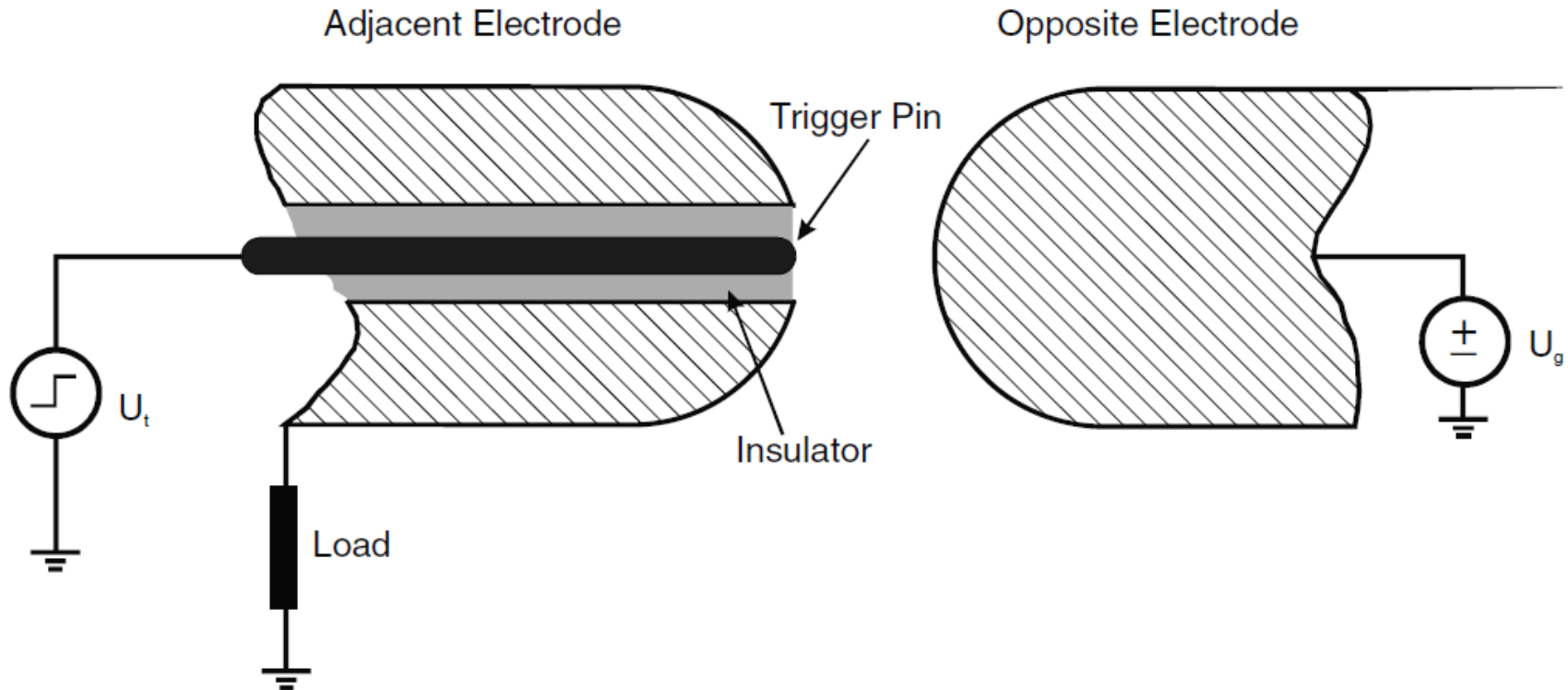
- Longitudinal-plasma triggering ($U_g < U_{b2}$)



- Longitudinal trigger can occur only for opposite polarities of the operating and triggering voltages.



Trigatron spark gap



- **Best trigger performance: trigger and operation voltage are opposite, i.e.,**

$$U_t \times U_g < 0$$

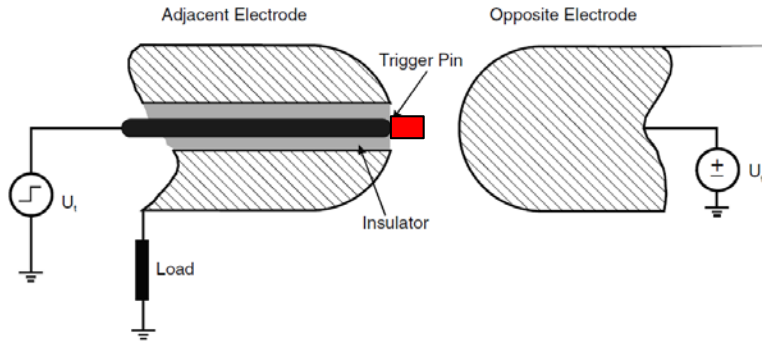
$$U_g \sim (80 \sim 99\%) U_b$$

- **$U_g \sim 50\% U_b$ is possible, but with large delay and jitter.**

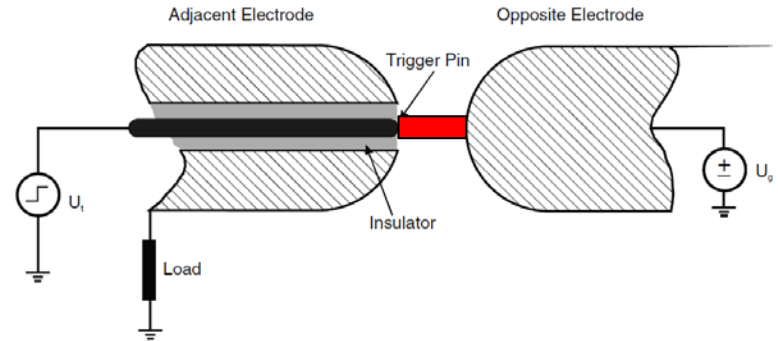
Trigatron spark gap – $U_t \times U_g < 0$



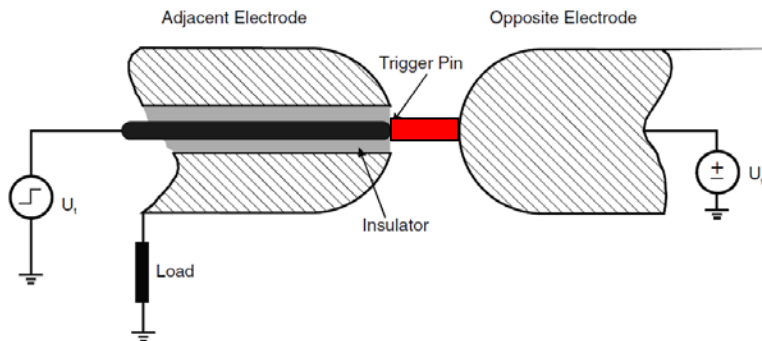
- **Step 1: Streamers begin to grow.**



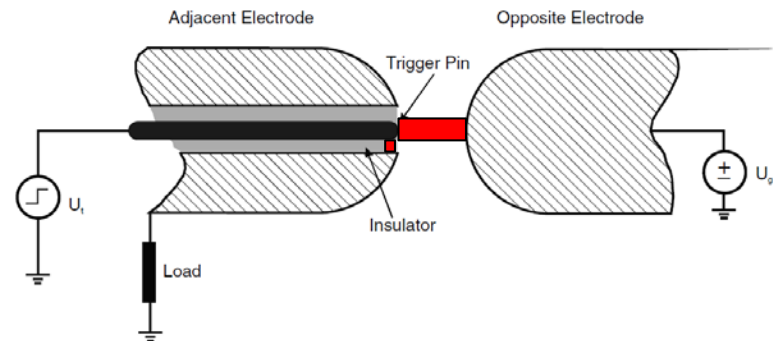
- **Step 2: ionization density in the channel to grow after streamer touch the electrode**



- **Step 3: conducting channel is formed.**



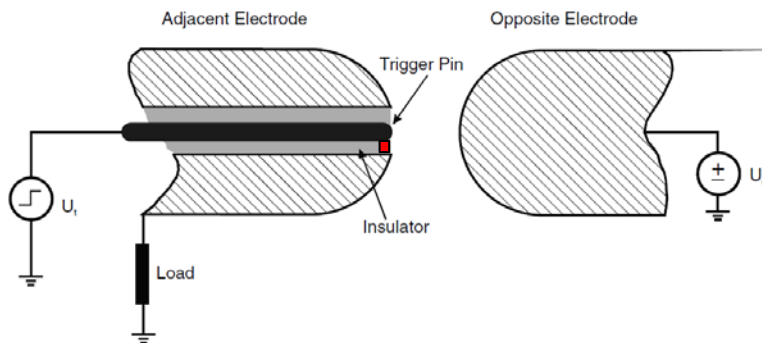
- **Step 4: two thermalized arcing connecting two electrode and pin.**



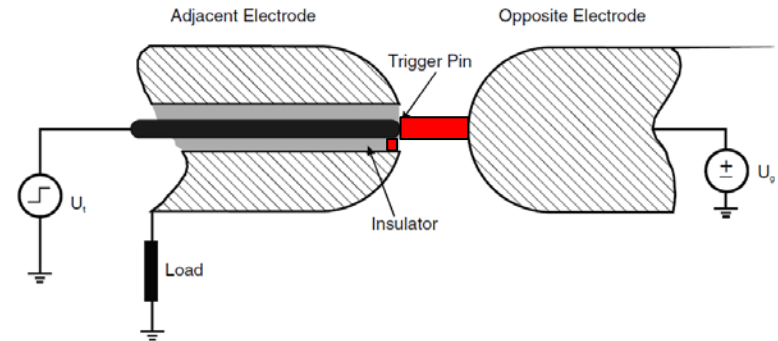
Trigatron spark gap – $U_t \times U_g > 0$



- **Step 1: breakdown between the trigger pin and the grounded electrode.**



- **Step 2: breakdown between two main electrodes occurs due to the UV radiation emitted from the 1st arc.**



- **Breakdown is possible but with large delay and jitter.**

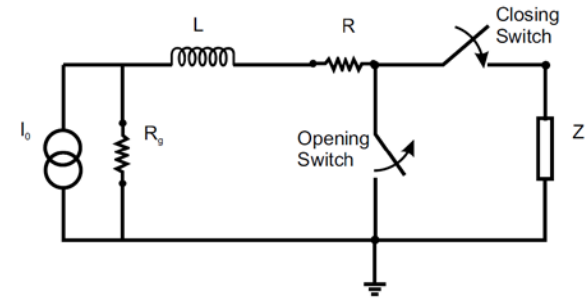
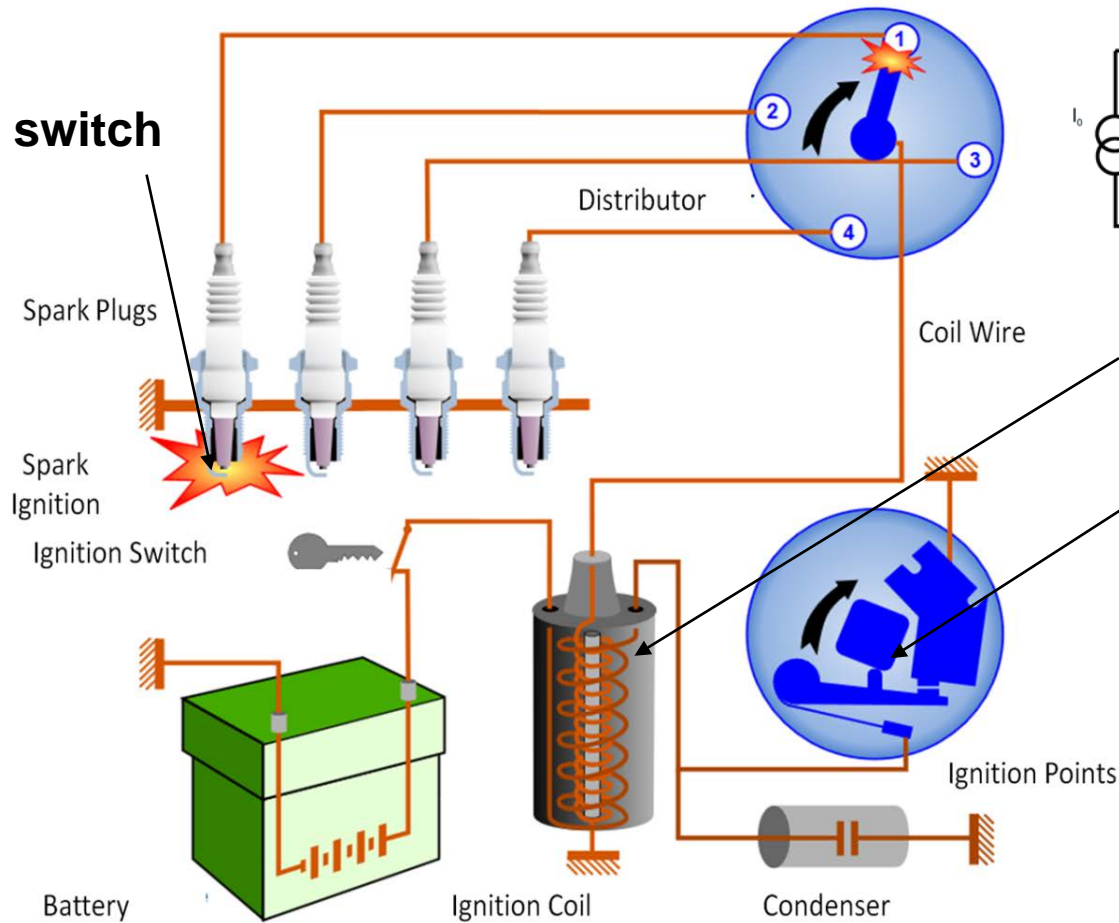
Spark plug is a Trigatron



Spark plugs in cars are triggered by the inductive energy storage



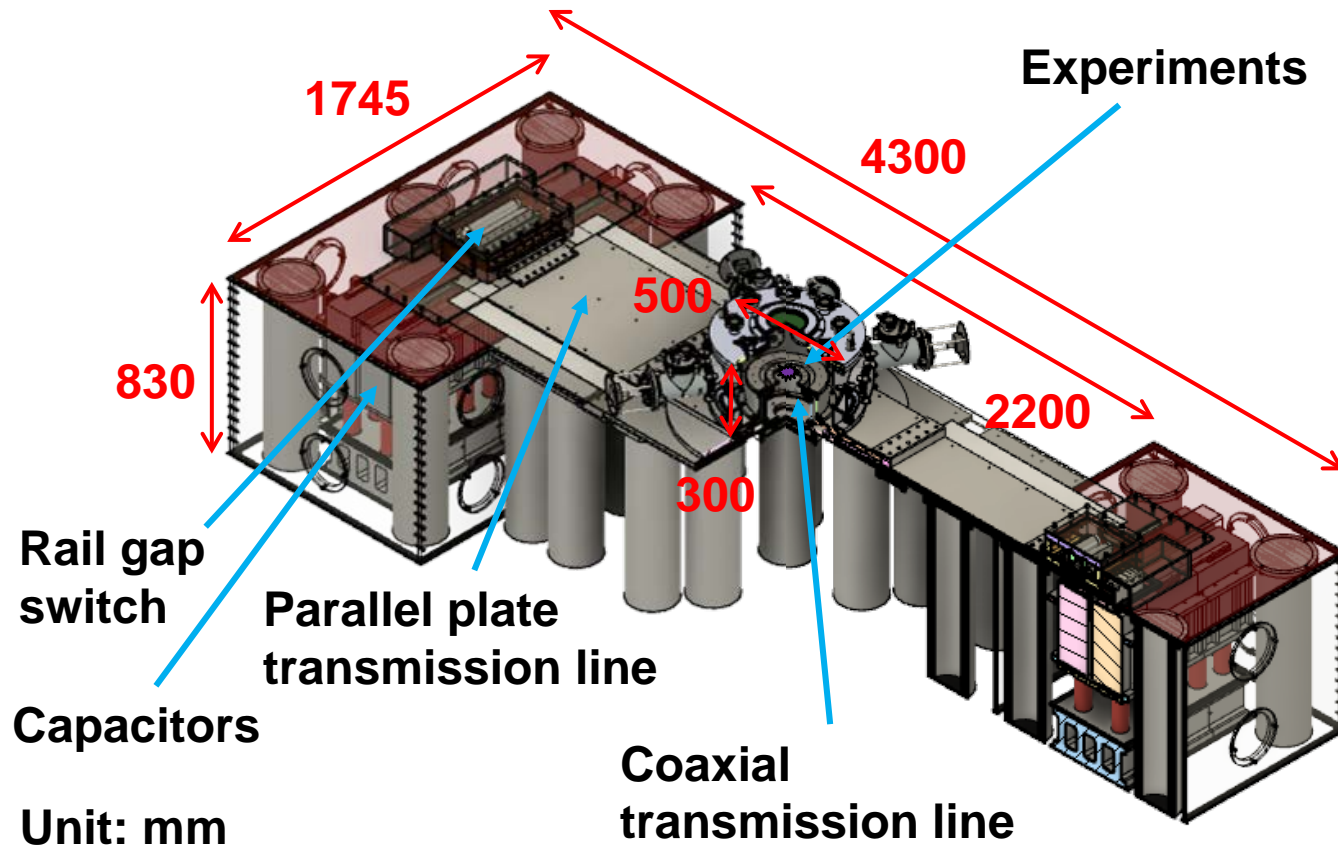
Closing switch /load



Inductive energy storage

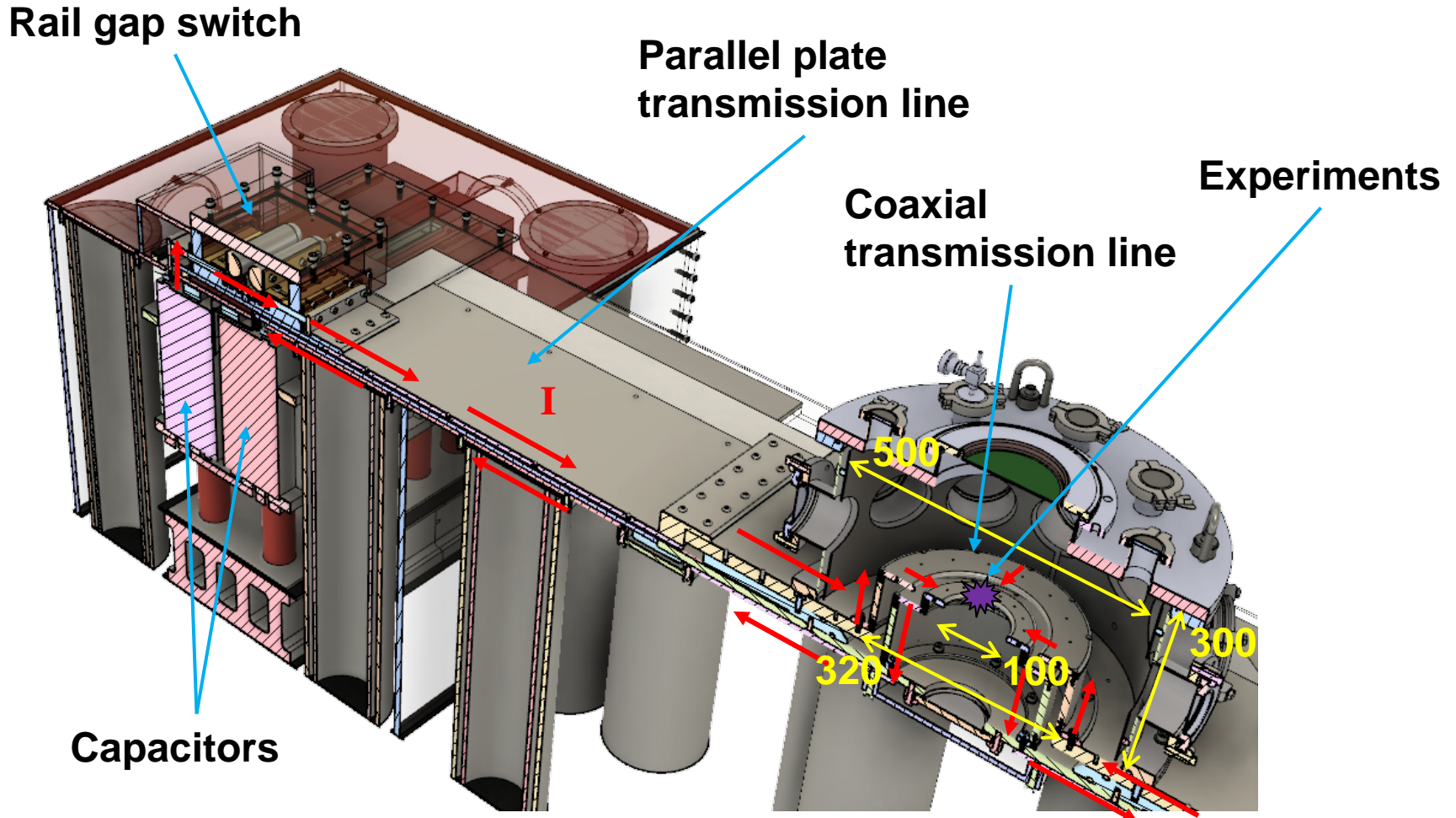
Opening switch

The pulsed-power system in Pulsed-Plasma Laboratory



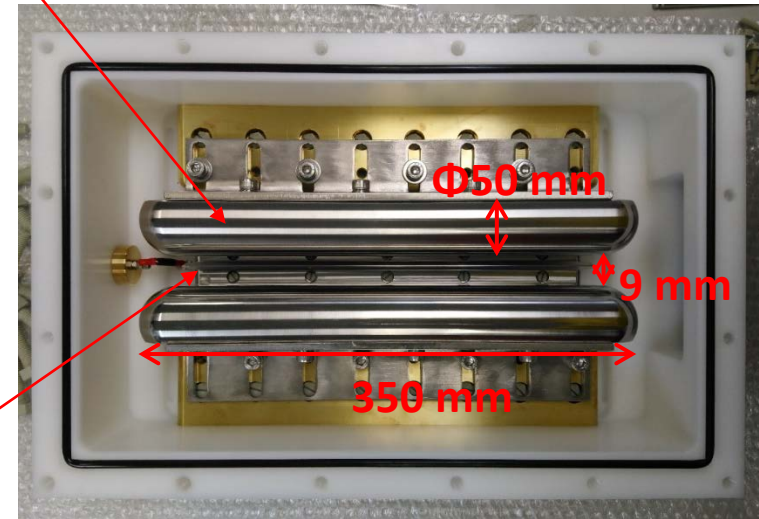
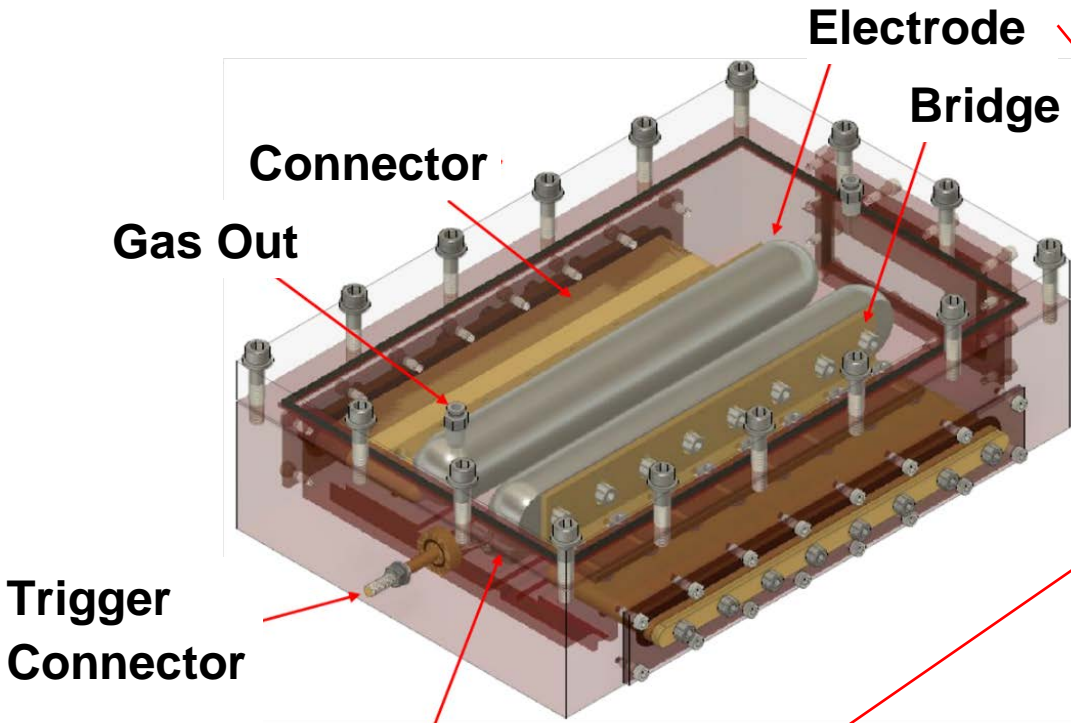
- A 1 kJ pulsed-power system at ISAPS, NCKU started being operated since September, 2019.

Experiments will be taken placed at the center of the vacuum chamber



Unit: mm

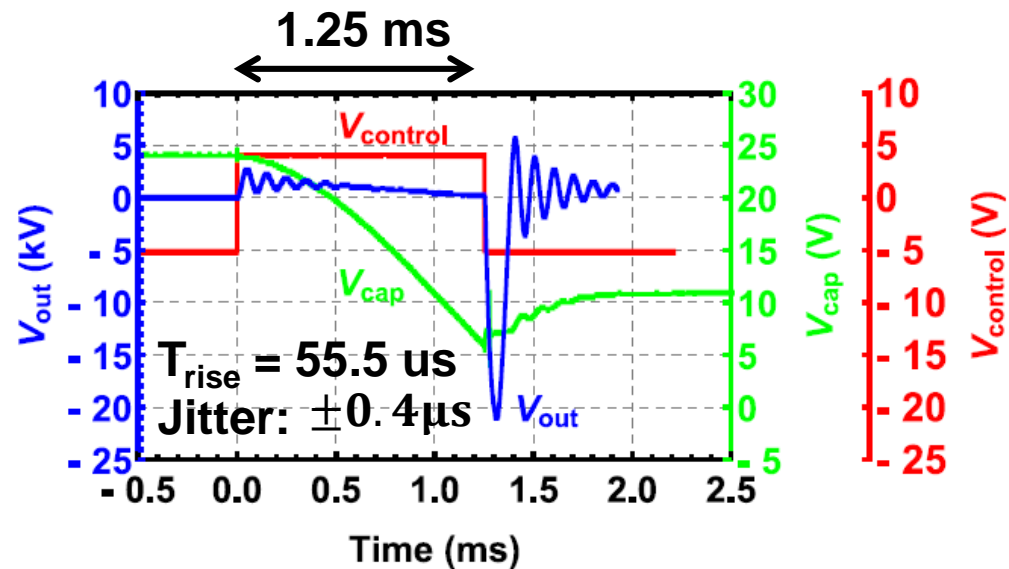
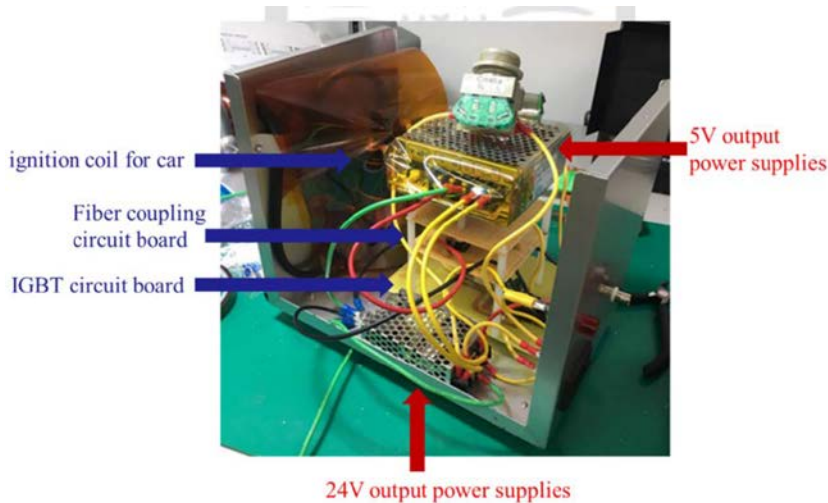
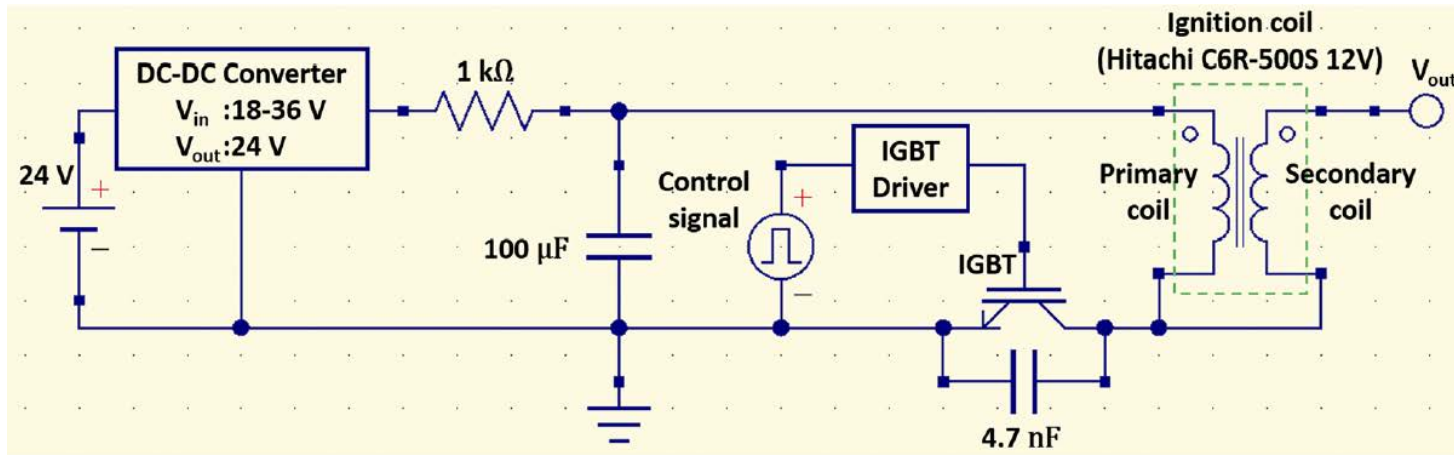
Low inductance rail-gap switches are used



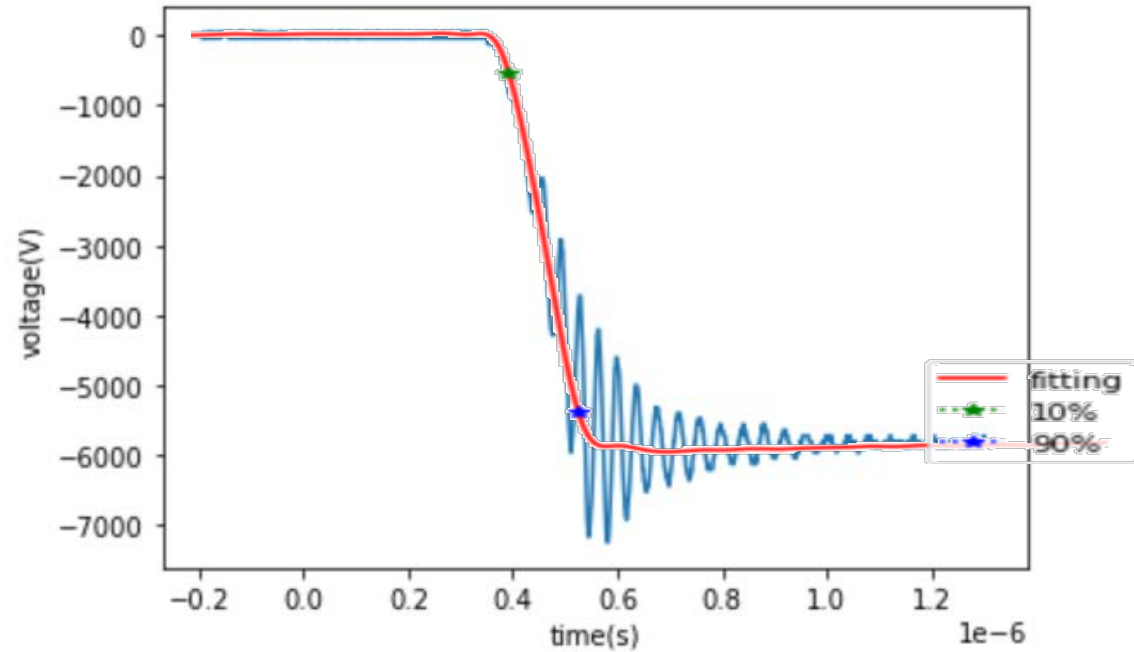
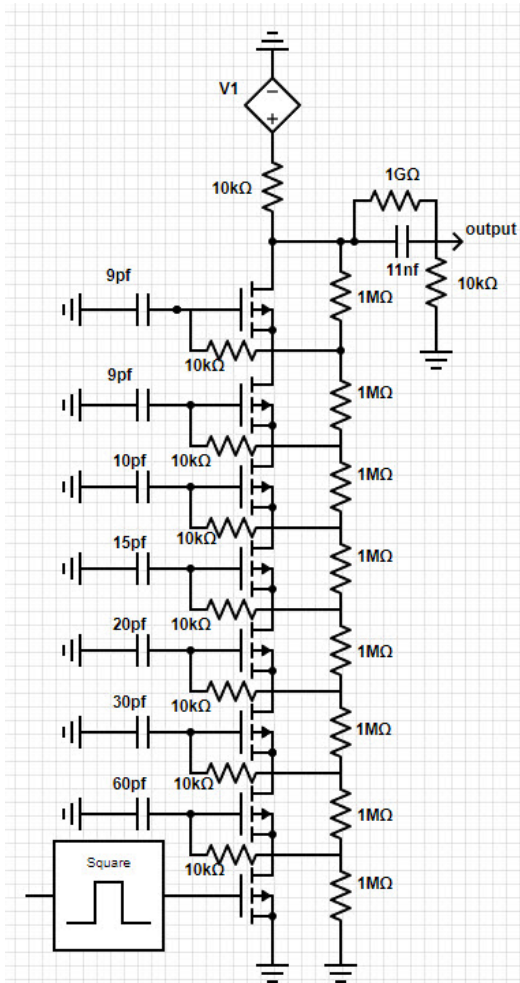
Knife edge trigger electrode

- The switch is pressurized with nitrogen gas (1~3 atm).
- Multi-channel discharges between two rail-like electrodes will be triggered by a fast trigger pulse generator (rising speed > 5kV/ns).

A slow trigger pulse generator was built using a ignition coil for cars

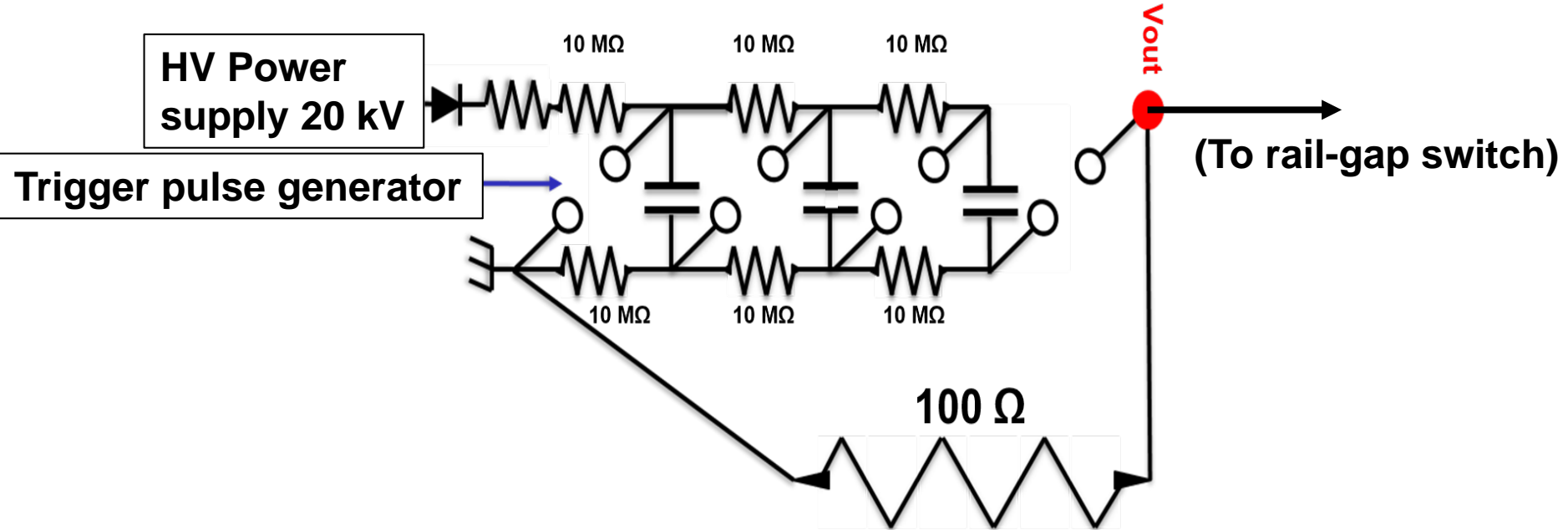


Many MOSFET connected in series can be used to provide a fast high-voltage triggering pulse



$$T_{\text{rise}} = 140 \pm 1 \text{ ns}$$

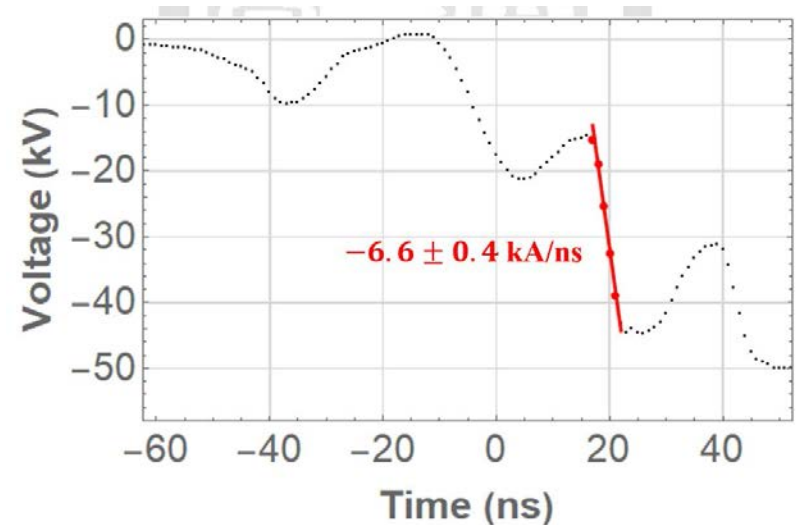
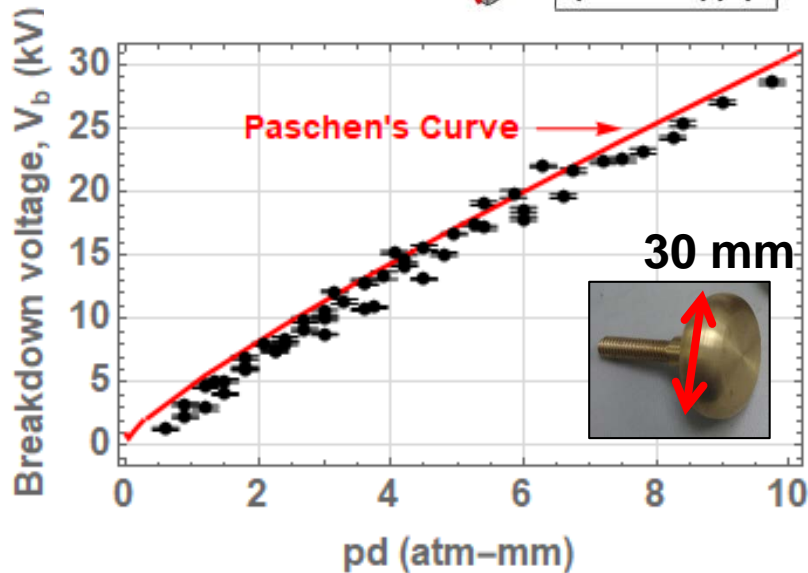
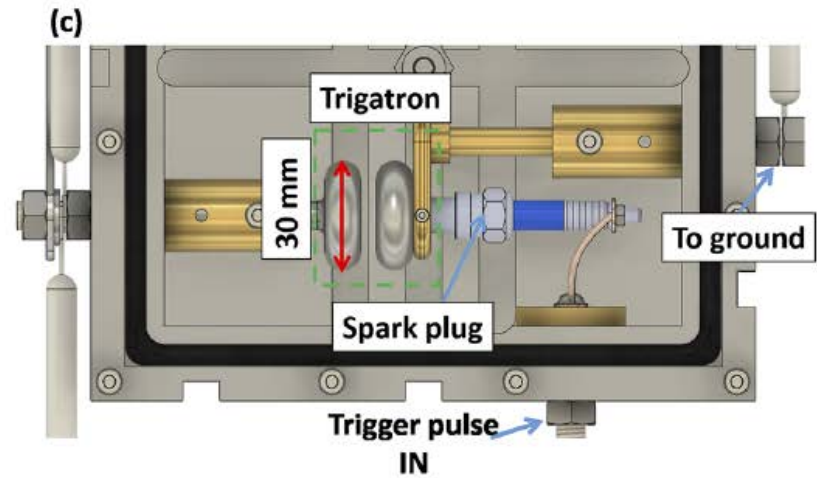
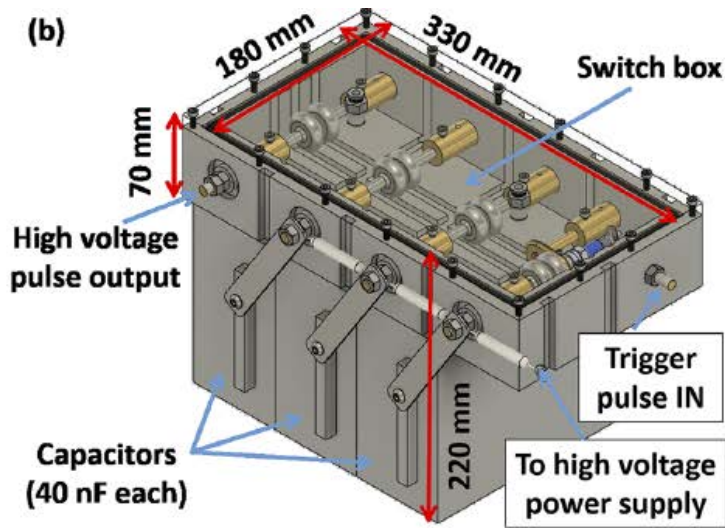
A three-stage Marx generator is used to provide a fast high voltage trigger pulse



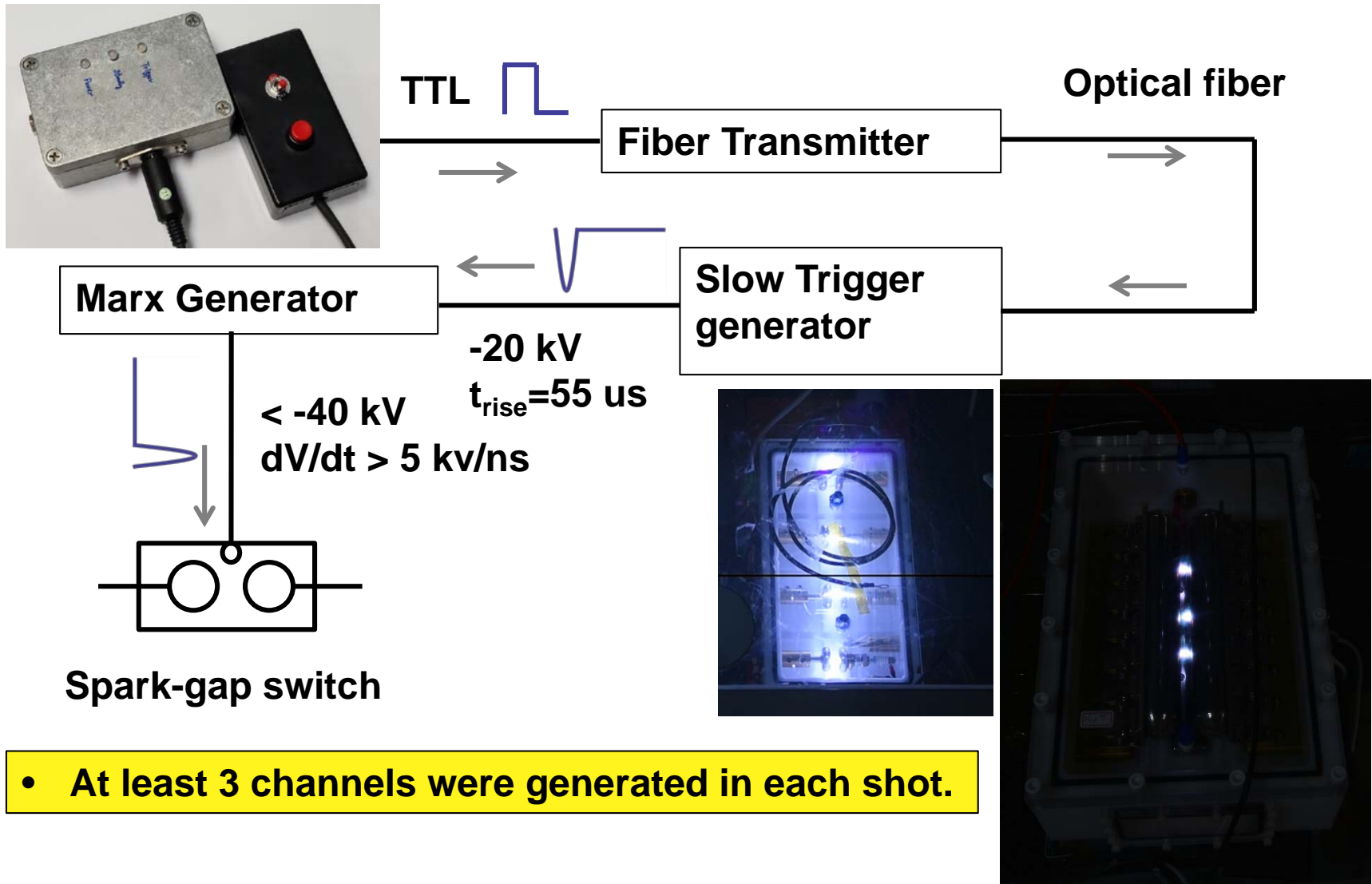
- In a Marx generator, capacitors are connected in parallel when they are being charged.
- Capacitors in the Marx generator are connected in series during discharge.

$$V_{\text{out, ideal}} = -N \times V_0 = -3 \times 20 \text{ kV} = -60 \text{ kV}$$

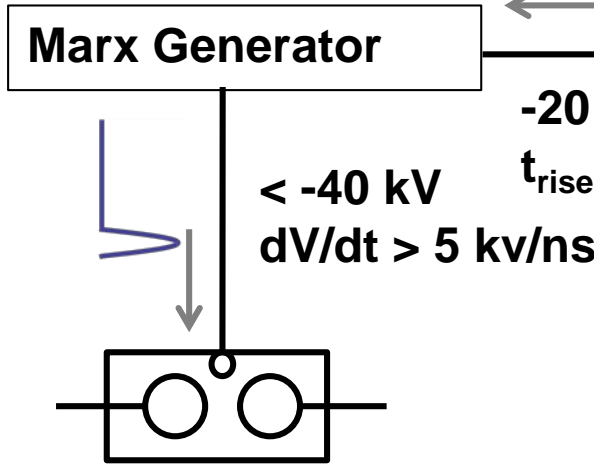
The falling speed of high voltage pulse from the Marx meets the requirement for triggering rail-gap switches



Multistep trigger system is used



Multistep trigger system is used

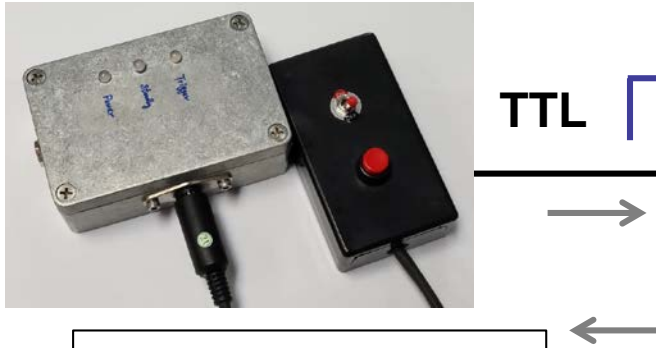


Spark-gap switch

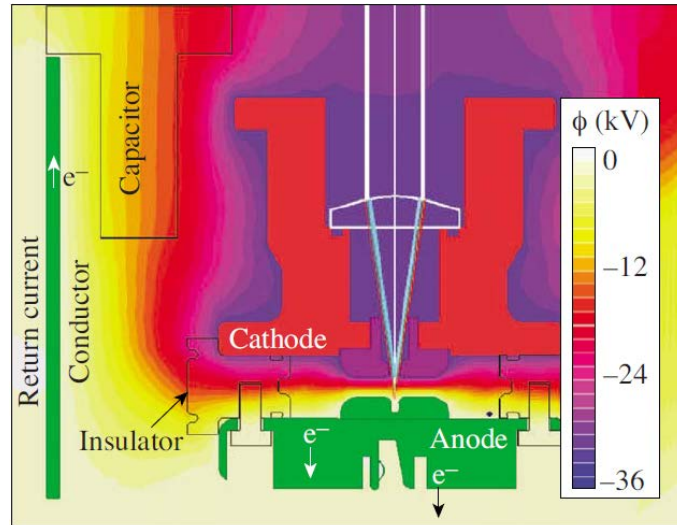
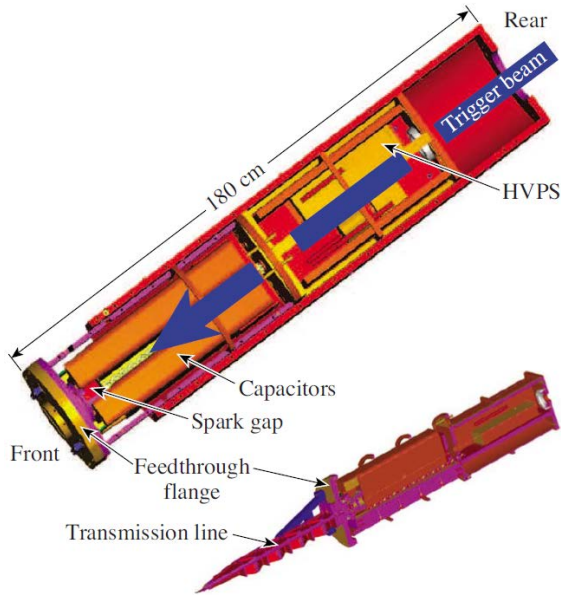


- At least 3 channels were

Multistep trigger system is used

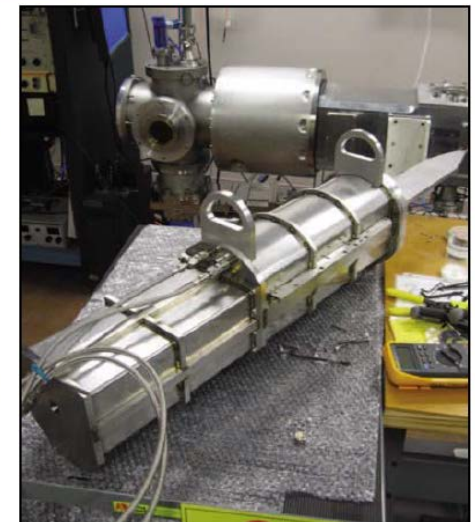
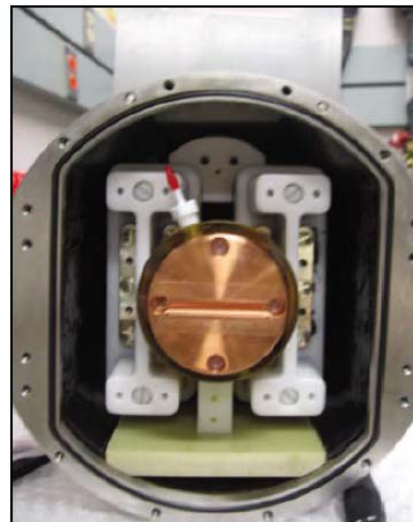
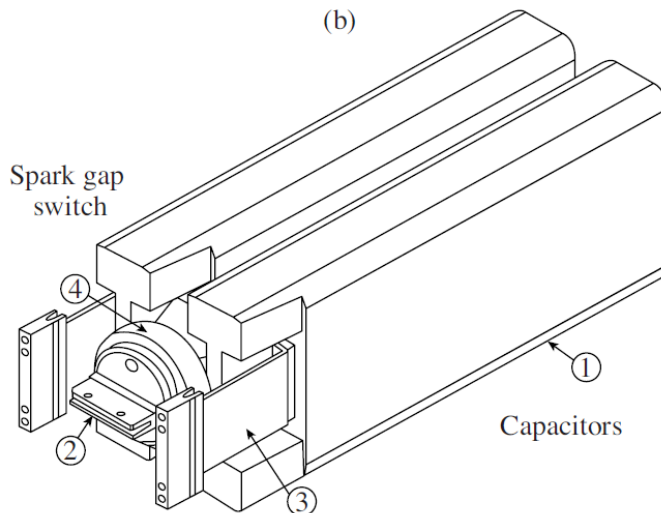


Magneto-inertial fusion electrical discharge system



6-7 ns pulse
 60 mJ @ 266 nm
 300 mJ @ 532 nm
 150 mJ @ 1064 nm

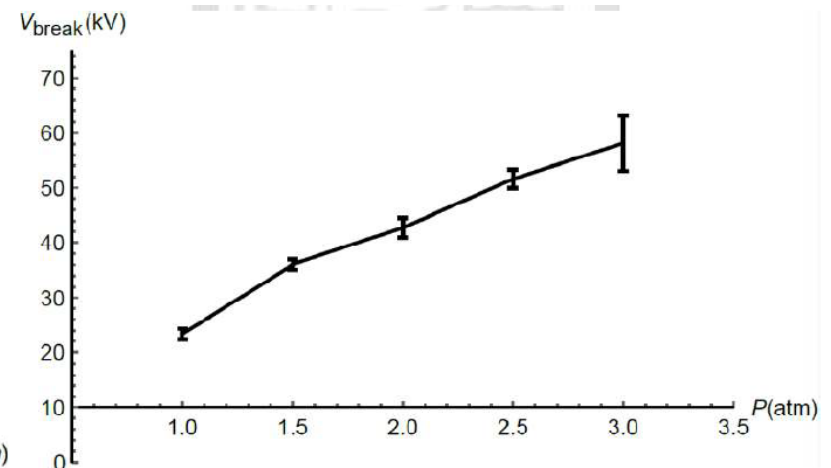
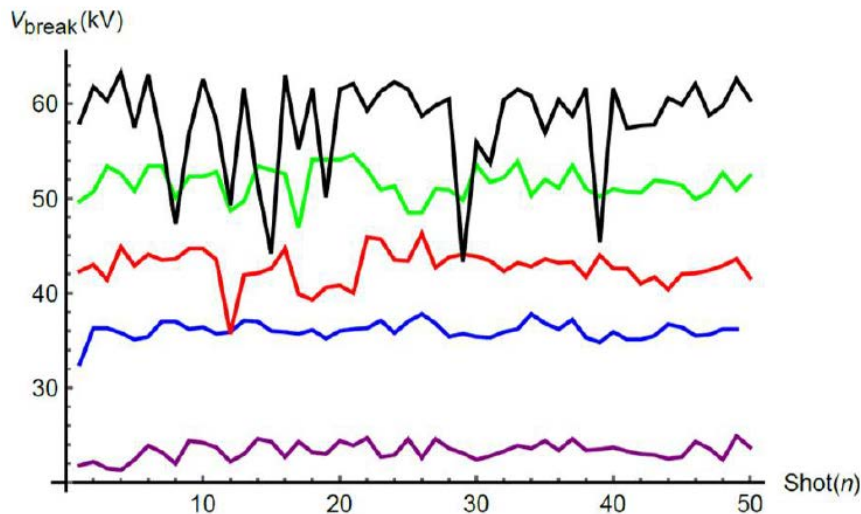
Delay: < 1 ns
 Jitter: < 1 ns



Breakdown uncertainty increases with a larger holding voltage



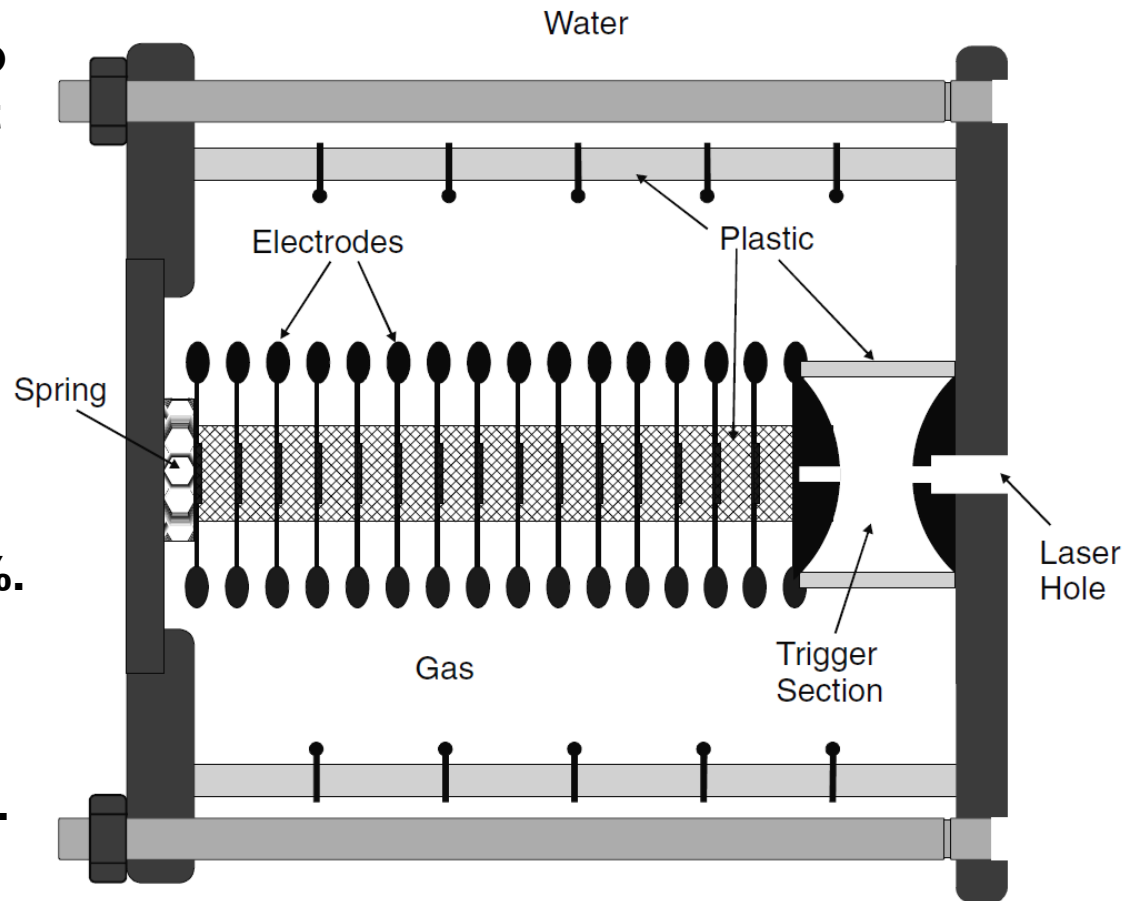
	Trigatron With Spacer	Trigatron No Spacer	SparkGap With 2 Spacer	SparkGap With 1 Spacer	SparkGap No Spacer
Gap	6 mm	9 mm	6 mm	9 mm	12 mm
Avg	17.49	24.55	19.21	28.86	35.83
Std	0.60	0.32	0.39	1.50	1.43
Max	18.70	25.10	19.80	32.40	38.60
Min	16.80	23.80	18.40	26.10	33.00



Multistage spark-gap switch with laser triggering



- Simply scaling a three-electrode spark gap to multimegavolt operating voltages would lead to large gaps, making the jitter and inductance unacceptably high.
- Operating voltage of up to 6 MV and a switch current of 0.5 MA.
- It consists of 15 equal spark gaps and a trigger section.
- The operating voltage is around 90% of the self-breakdown value with a prefire probability of 0.1 %.
- The gap capacitances are small, 20 % of the operating voltage occurs across the trigger section.



Multistage spark-gap switch with laser triggering



- The switch is 68 cm long and 61 m in diameter.
- The 1st gap is 5.7 cm and a UV laser pulse (KrF) with a 25 mJ pulse energy is necessary.
- ~1 ns after the laser pulse, a breakdown occurs in the trigger gap and the voltage increases across the remaining gaps rapidly. An ignition wave propagates to the other gaps and ignites them sequentially.
- Total inductance: 400 nH; Trigger delay: 20 ns; jitter <0.4 ns.

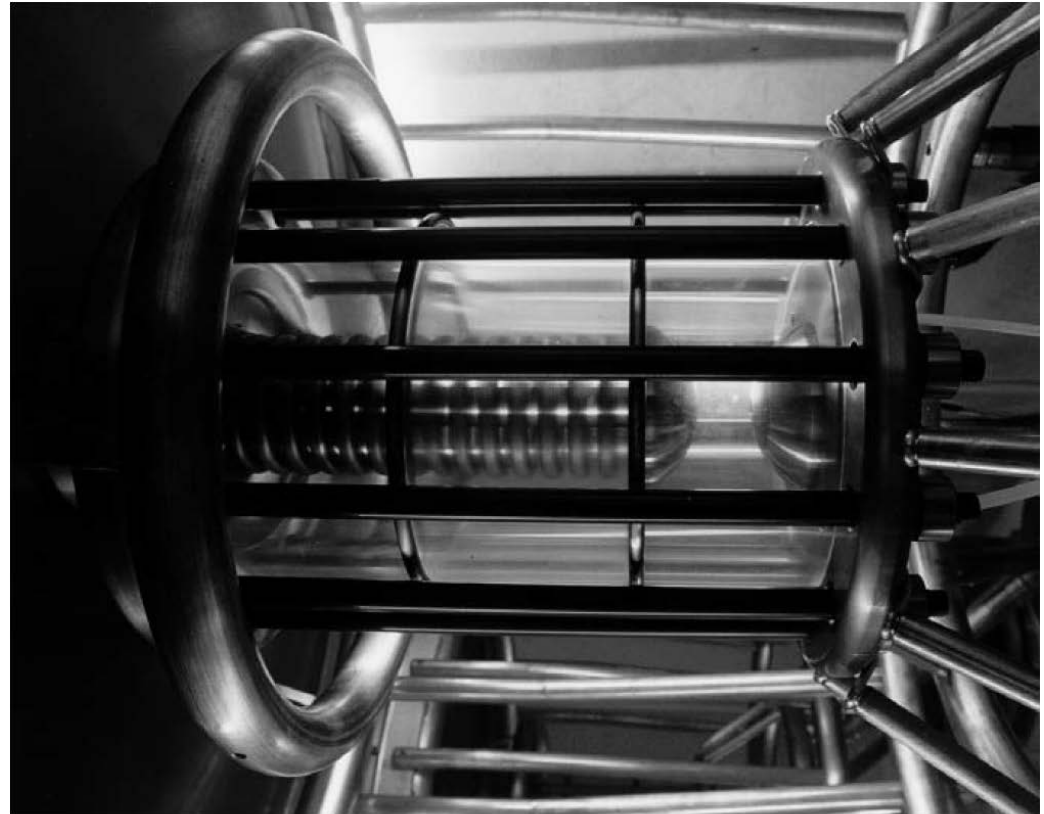
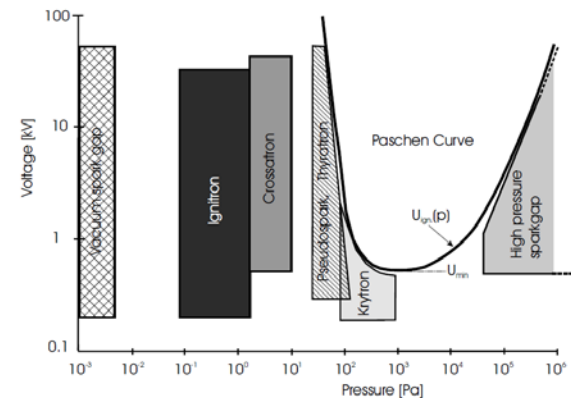
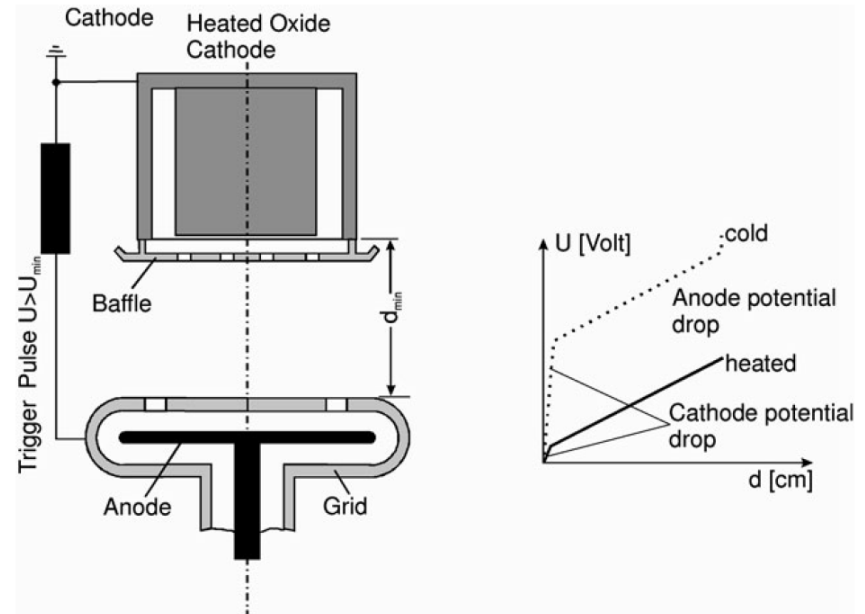


Fig. 4.13. A 4 MV version of a multigap spark switch

Thyratrons



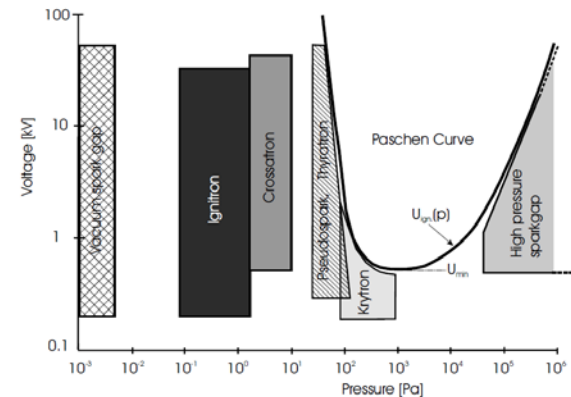
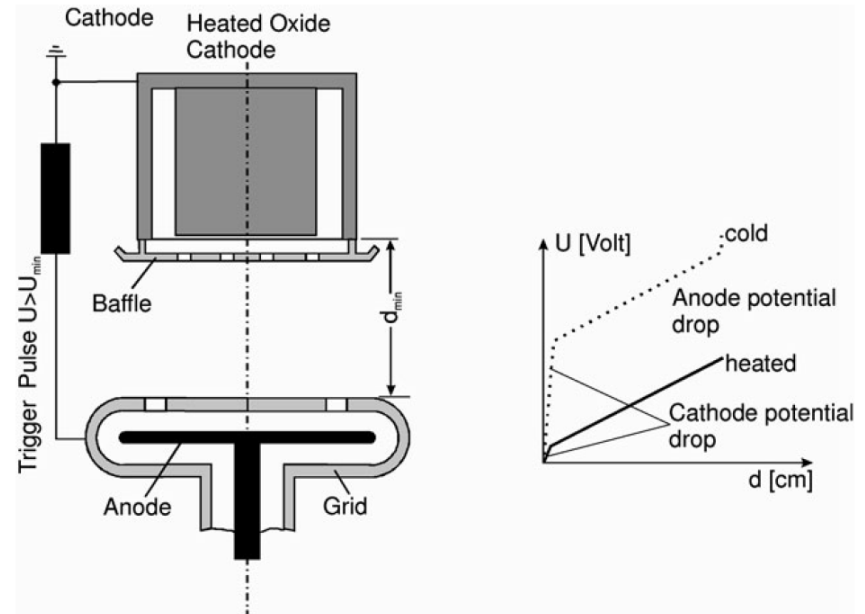
- Thyratrons are gas-filled switching devices with a gas pressure (30-80 Pa/ $3 \times 10^{-4} - 8 \times 10^{-4}$ atm) much lower than a spark-gap switches.
- A triode configuration is used.
- The thyratron is characterized by the presence of a plasma, which allows the passage of large currents without significant electrode erosion.
- The hold-off voltage is limited by field emission, $> 10^5$ V/cm.
- The anode-grid distance is 2-3 mm, ~ 40 kV hold-off voltage.



Thyratrons



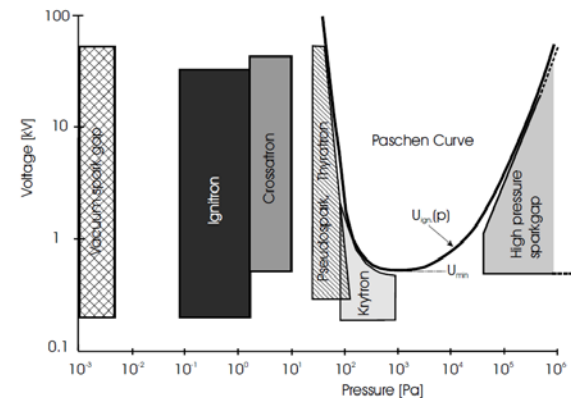
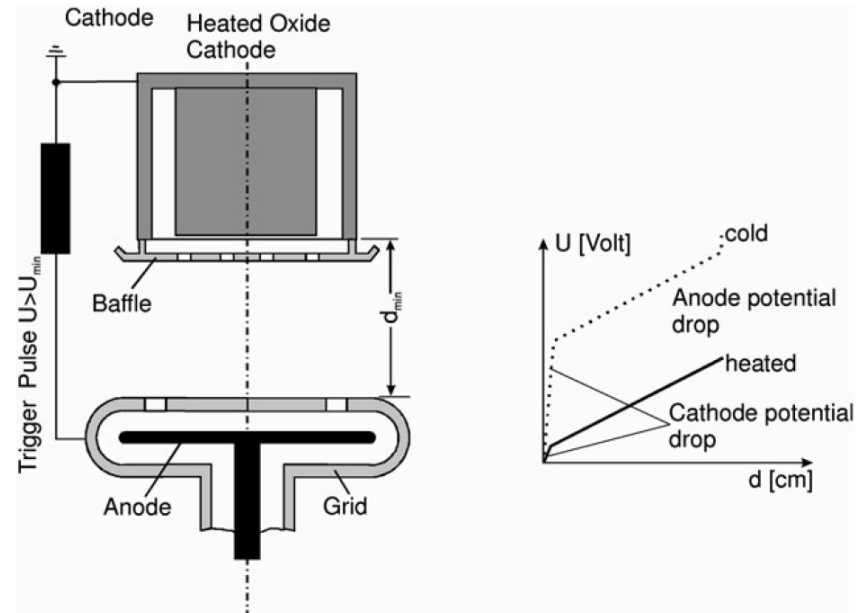
- The cathode-grid distance corresponds to the Paschen minimum U_{\min} .
- If $U > U_{\min}$, a glow discharge is initiated between the cathode and the grid. \Rightarrow electrons from the glow discharge plasma can migrate rapidly through the openings in the grid to the main discharge region between the grid and the anode. \Rightarrow thyratron closes.



Thyratrons



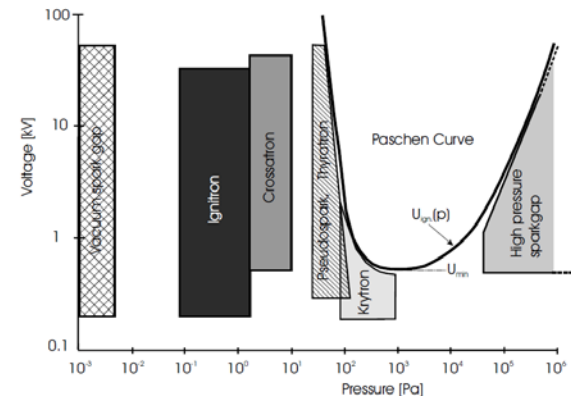
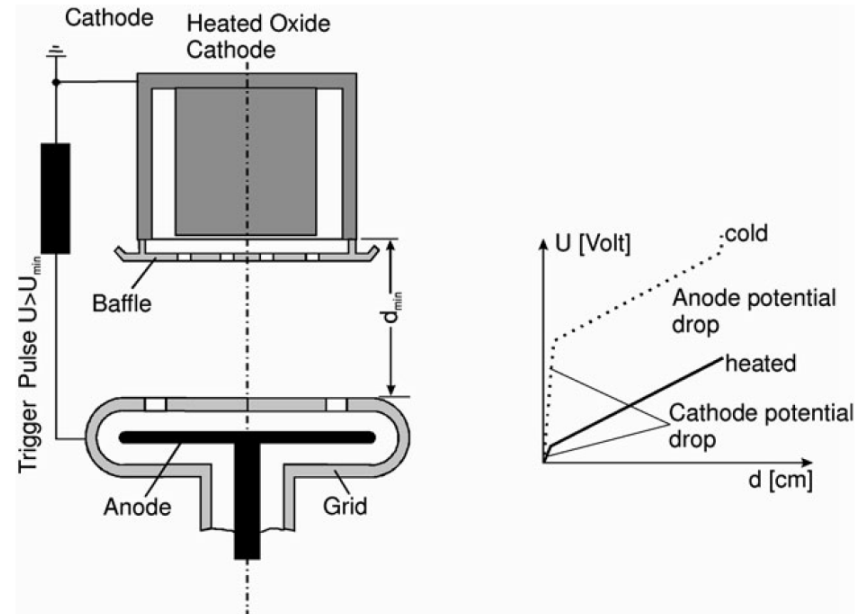
- **Operating voltage:** several times 10 kV. After ignition: ~ 100 V \Rightarrow an appreciable power loss occurs and need to be dealt with by cooling.
- **Delay:** ~ 200 ns; jitter: \sim ns.
- **Operating times:** 10^5 hours;
Repetition rates: few kHz;
Operating power: MW.
- **To regain the initial hold-off voltage:** anode voltage must become slightly negative for 25-75 us for plasma to decay.



Thyratrons



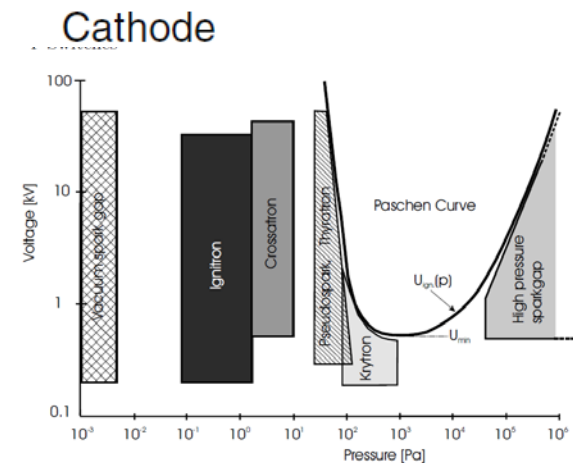
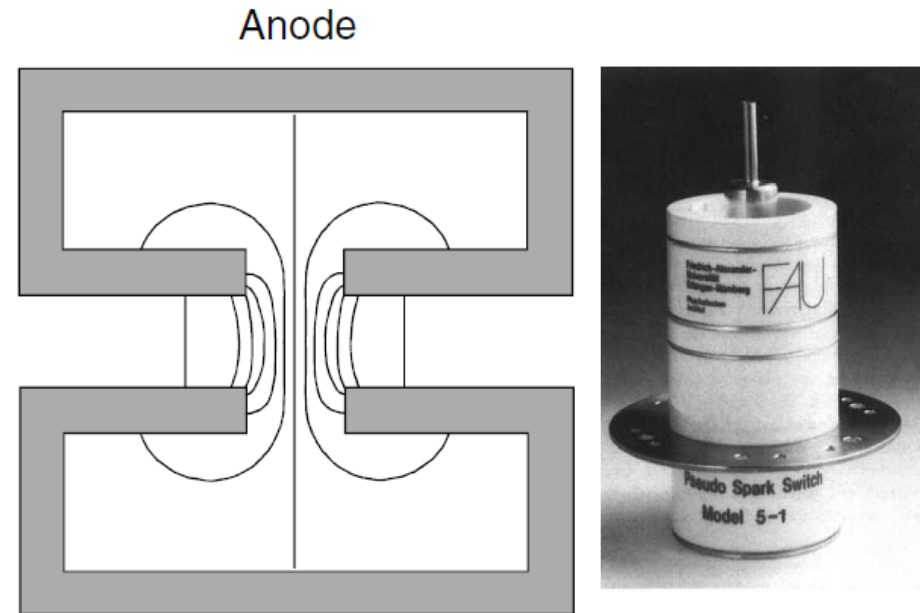
- A thermionic cathode is used in a thyratron.
- Advantage: absence of a marked cathode potential drop using hot cathode.
- If cold cathode is used, potential drop is needed to accelerate the ions for secondary-electron production => lead to erosion of the cathode and thus the lifetime.
- A baffle is used as a screening element to avoid electron directly reaching the anode and causing the damage. It is shifted relatively to the grid to prevent a direct line of sight between cathode and anode.



The pseudospark switch



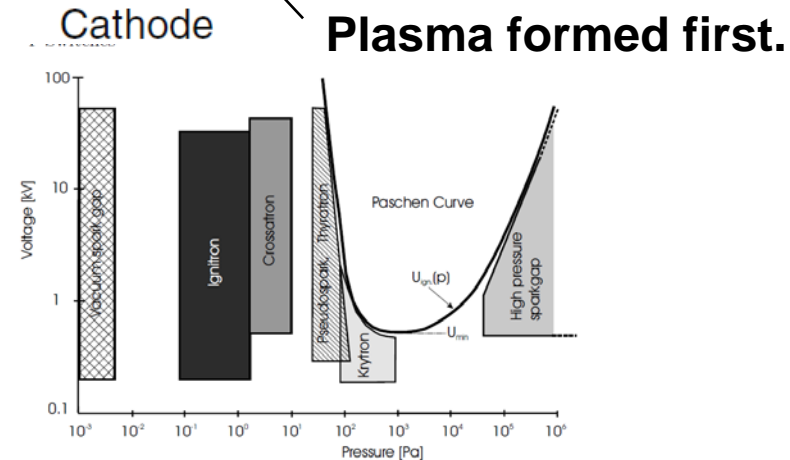
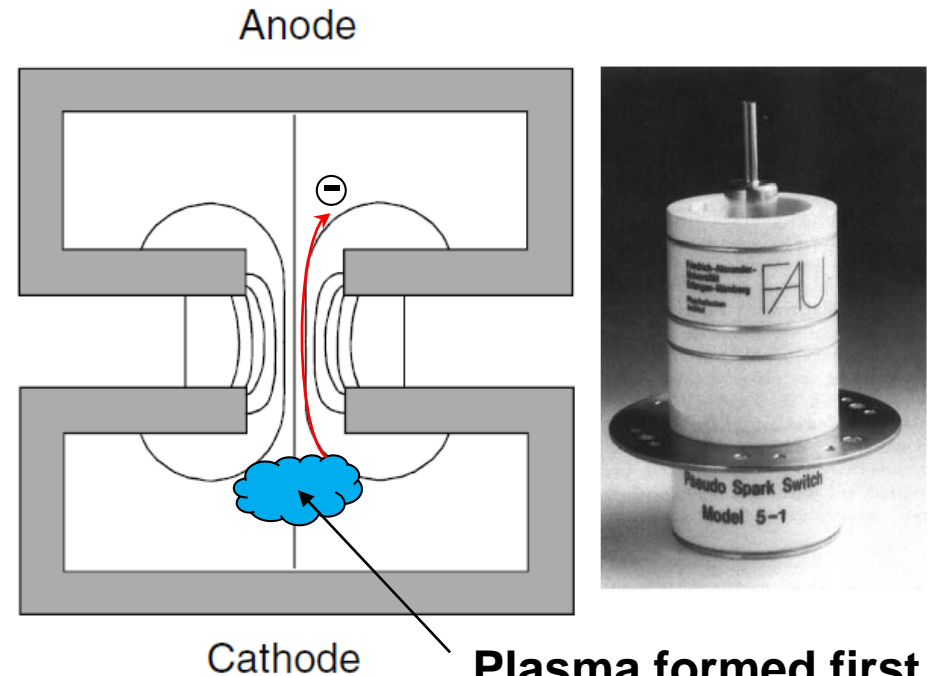
- The pseudospark switch operates in a low-pressure regime, where the mean free path of electrons and ions become comparable to the electrode spacing. Most electrons reach the anode without any ionizing collisions in the gas.
- Hollow cathode: increases the possible discharge path lengths.
- The diameter of the aperture determines the field penetration into the hollow cathode.



The pseudospark switch



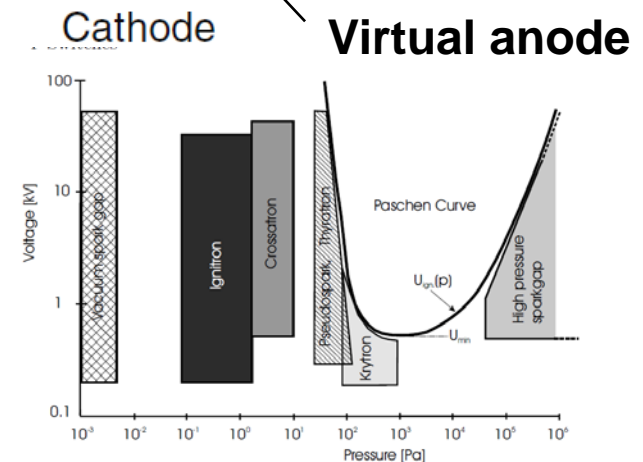
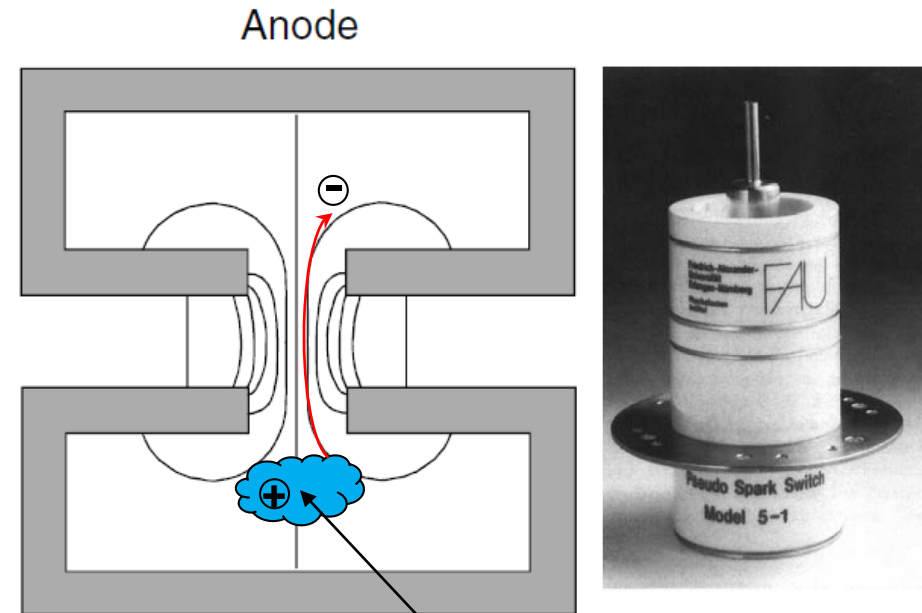
- A small number of initial electrons, triggered discharge in the hollow cathode can initiate the pseudospark discharge.
- The switching mechanism is based on the build-up of a highly ionized plasma.
- plasma build-up occurs first inside the hollow cathode where E/P is low.



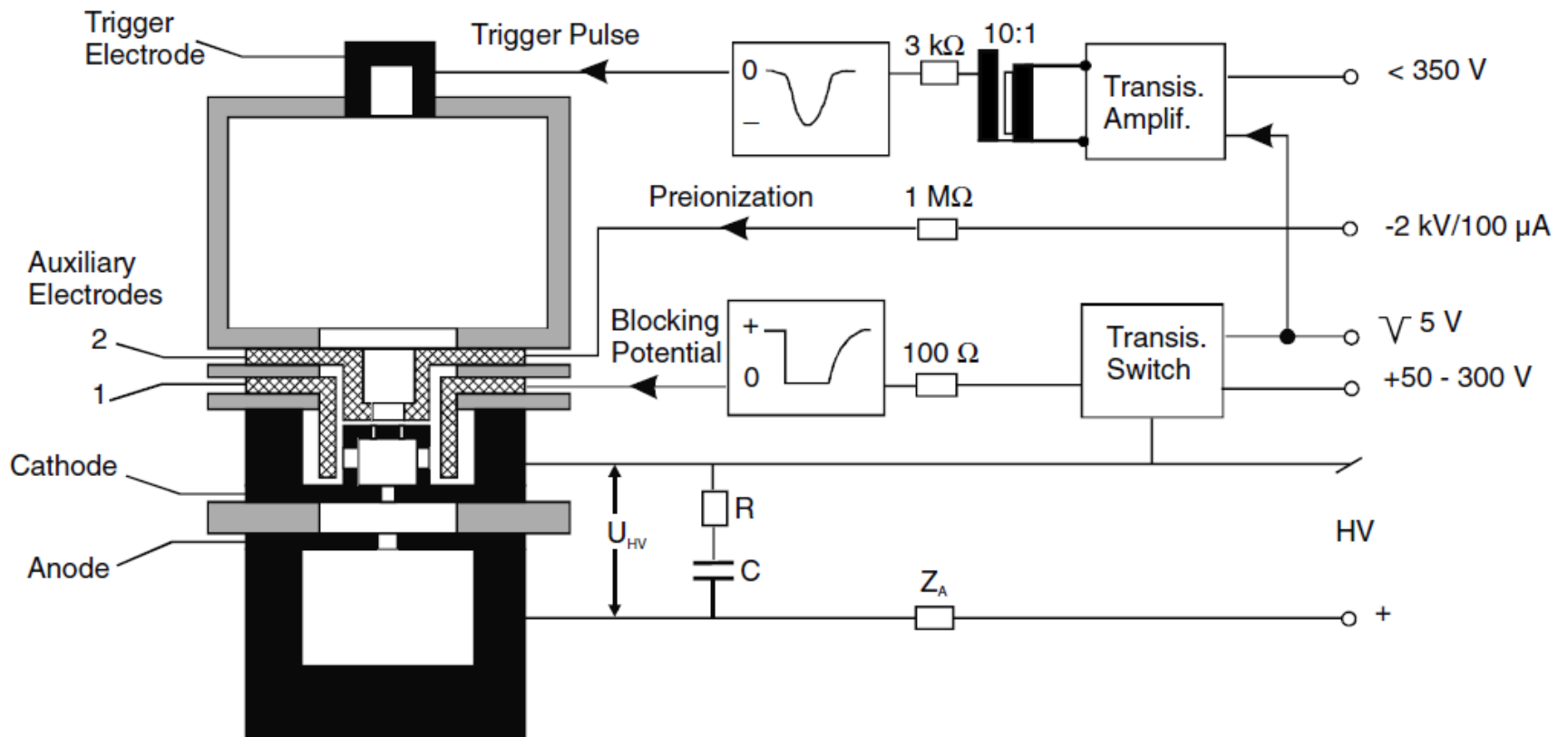
The pseudospark switch



- Ions drift back into the hollow cathode => forming a positive space charge (virtual anode).
- Static electric field inside the hollow cathode is distorted.
- Electron production rate > loss rate in the hollow cathode and subsequently in the anode-cathode gap.
- A low-resistivity plasma is established, and breakdown of the gap occurs.
- Jitter: 10 ns; Delay: 0.5 us.
- Advantage: high di/dt , reverse current, long lifetime, low jitter.



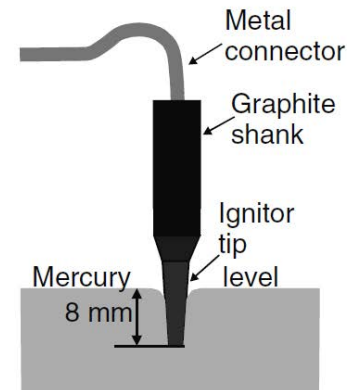
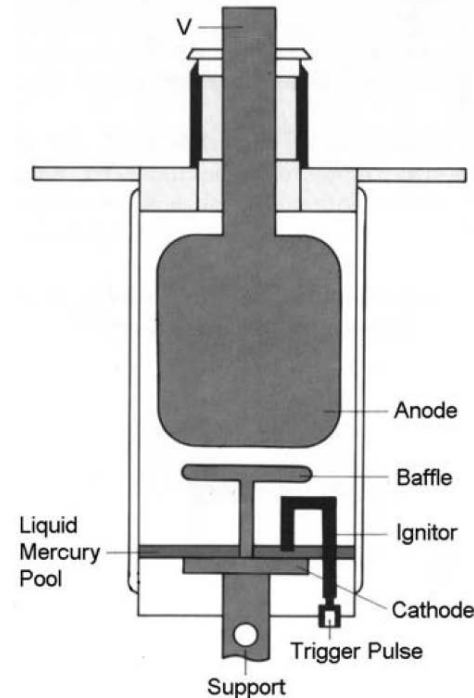
The pseudospark switch with triggering system



Ignitrons



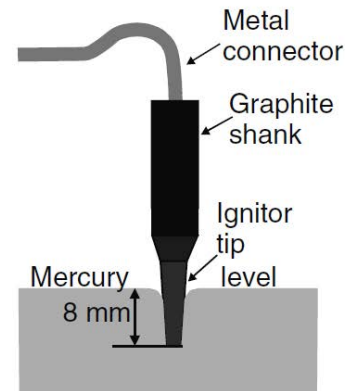
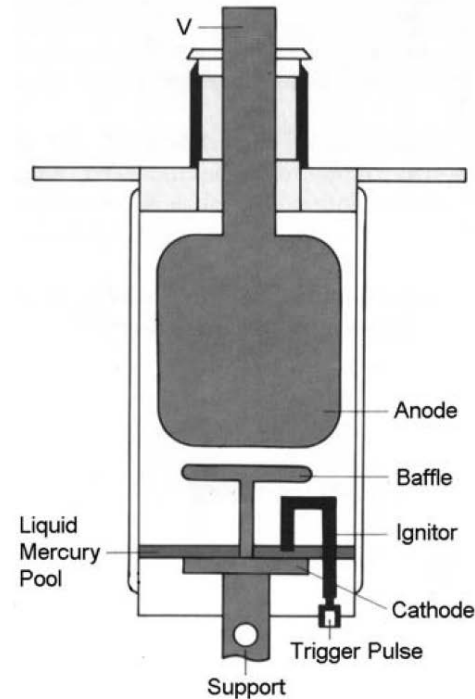
- Ignitron is a very high-current, high-voltage switch with
 - a liquid mercury pool cathode
 - an ignitor pin dipping into the liquid-metal reservoir.
- Internal mercury pressure: ~ 5 Pa
- Can switch a pulse charge of up to 2000 Colum.
- Air/water cooled may be needed.
- Internal splash and deionization baffles may be contained in some devices.
- Anode:
 - Anode is massive to prevent an impulsive temperature rise during conduction.
 - Anode is cooled through
 - (1) anode stem;
 - (2) radiation to the cooled walls.



Ignitrons



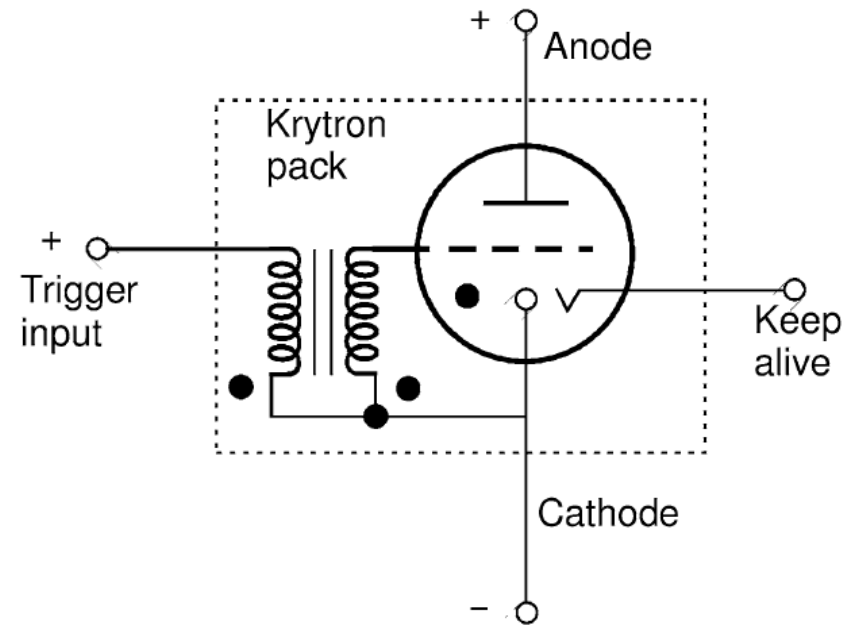
- Rise time ~ 300-500 ns.
- After current drops below a critical value => no more additional vapor is produced => with additional time to allow recombination and recondensation of mercury.
- The mercury vapor must be forced to recondense back into the pool.
- Repetition rate ~1 Hz
- Progressively eliminated due to the mercury-containing waste.



Krytrons



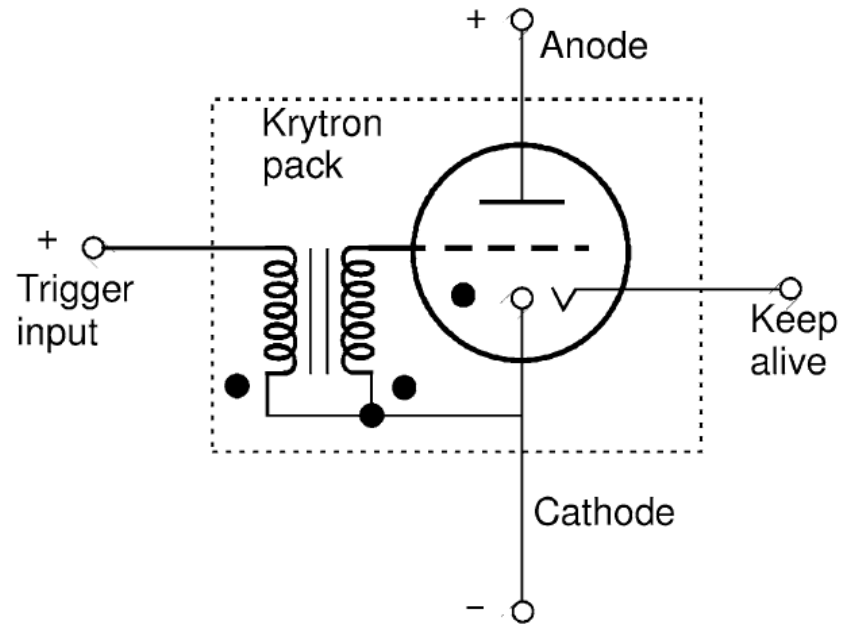
- **Low-pressure gas discharge device with a tetrode configuration, sealed in a glass tube with a cold cathode.**
- **1.3 kPa (9.75 torr) of helium gas.**
- **A special design of the anode-grid area + applied gas pressure => large hold-off voltage.**
- **An already existing plasma is created by a glow discharge between the special keep-alive electrode and the cathode.**
=> short trigger delay: ~30 ns.
- **Rise time: ~1 ns, V_{max} : 8kV, I_{max} : 3 kA.**
- **Pulse length ~10 us, repetition rate ~1 kHz**
- **A positive pulse at the control grid initiate the switch.**



Krytrons



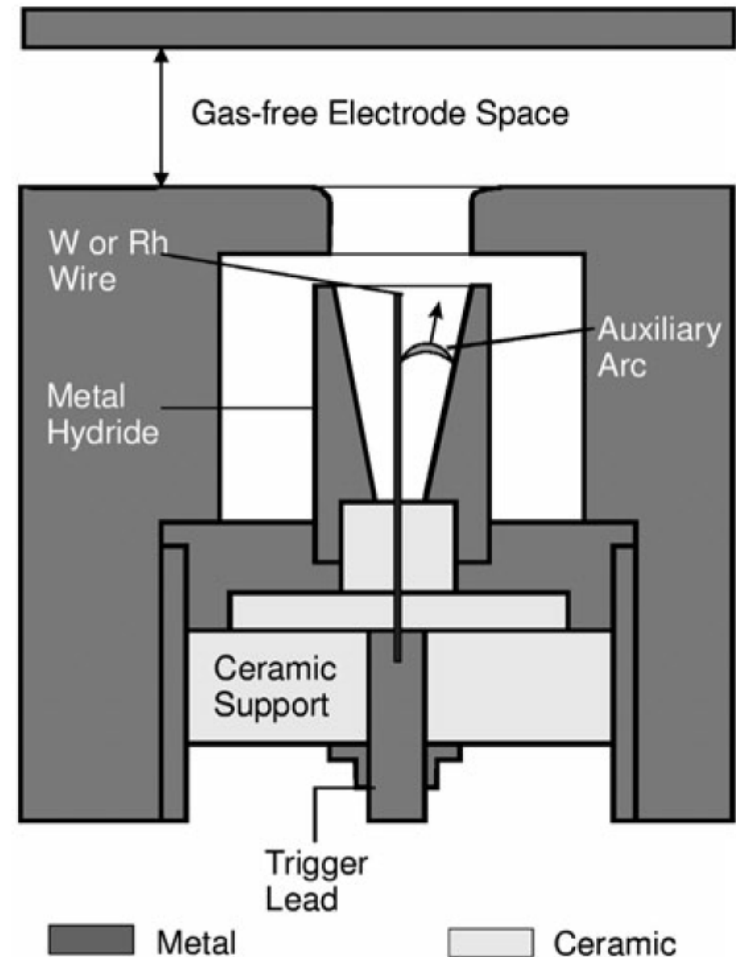
- A ^{63}Ni β -emitter may be enclosed to create a weak permanent pre-ionization.
- It is widely used in fast trigger generators and Pockels cell driver and also ideal for use in the detonating circuitry of bombs.



Triggered Vacuum Gap (TVG)



- A three-electrode system with $P=0.001 \text{ Pa}$ ($7.5 \times 10^{-6} \text{ Torr}$).
- Closed by injection of a plasma cloud.
- Hold-off voltage depends on the properties of the electrode surfaces.
- I up to 10 kA, V up to 100 kV. Repetition rates of several kHz are possible if cooled.
- The gas-plasma mixture is created with the help of an auxiliary arc, burning between two electrodes inserted into one of the main electrodes.
- Jitter $\sim 30 \text{ ns}$; switching time $\sim 100 \text{ ns}$.



Semiconductor closing switches



- **The limiting switching characteristics of semiconductor devices are:**
 - **Relatively low mobility**
 - **Low density of charge carries**
 - **Comparatively low operating temperature**
- => Large volume of the conducting region is required to conduct large currents.**

Thyristors

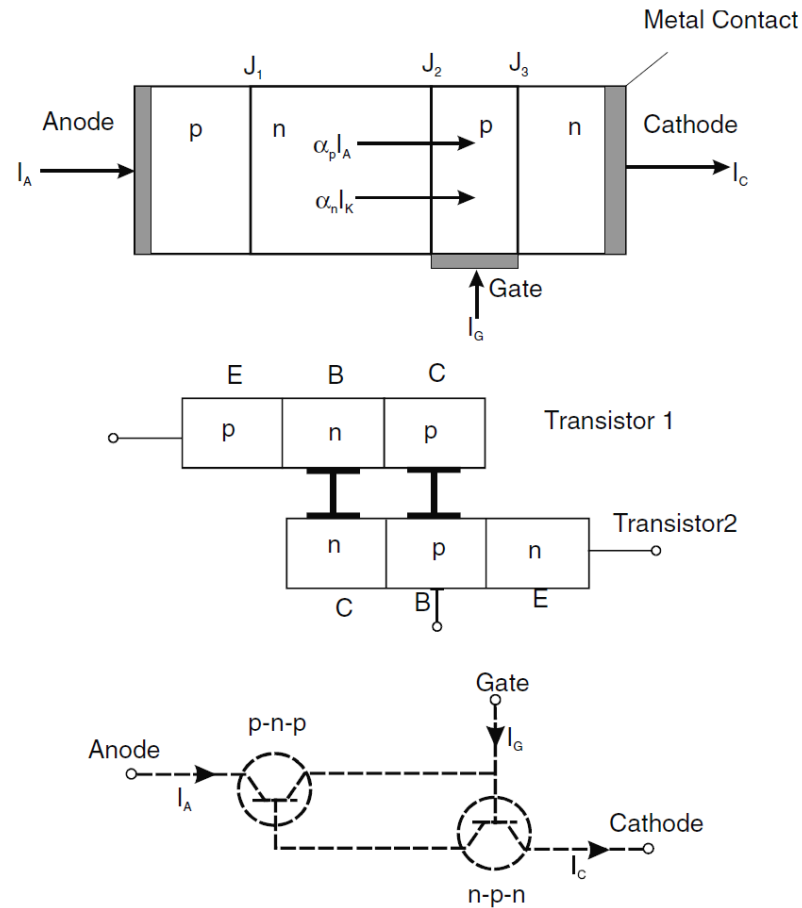
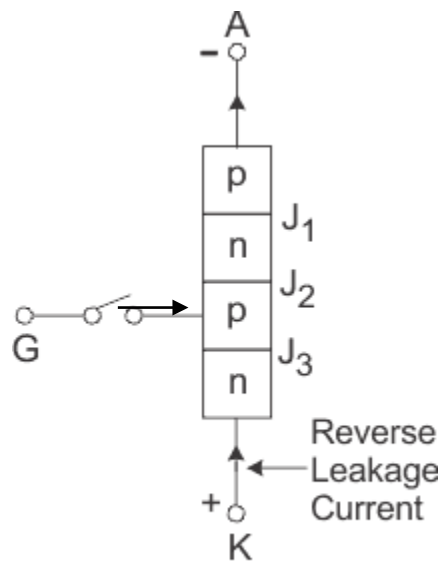


Fig. 4.22. Structure of thyristor, and two-transistor equivalent circuit

Thyristors

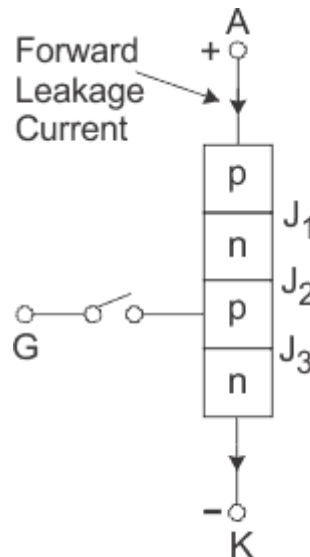


- Three modes of operation:
 - Reverse blocking state
 - Forward blocking state
 - Conduction or on state



Reverse Blocking Mode

Most of the voltage is held by J_1 .



Forward Biased Condition

Most of the voltage is held by J_2 .

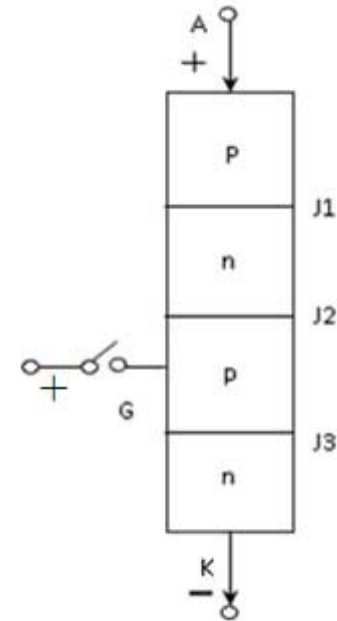
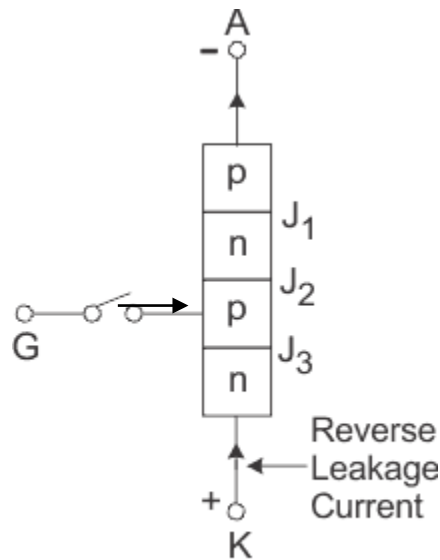


Fig 2: Forward Conduction

Thyristors

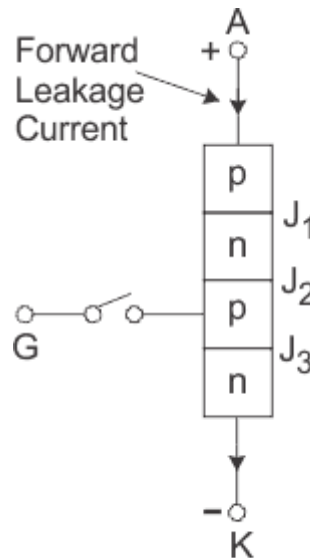


- Three modes of operation:
 - Reverse blocking state
 - Forward blocking state
 - Conduction or on state



Reverse Blocking Mode

Most of the voltage is held by J_1 .



Forward Biased Condition

Most of the voltage is held by J_2 .

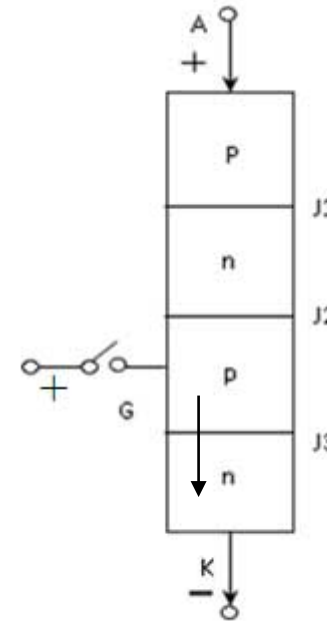


Fig 2: Forward Conduction

e^- will fill up the holes

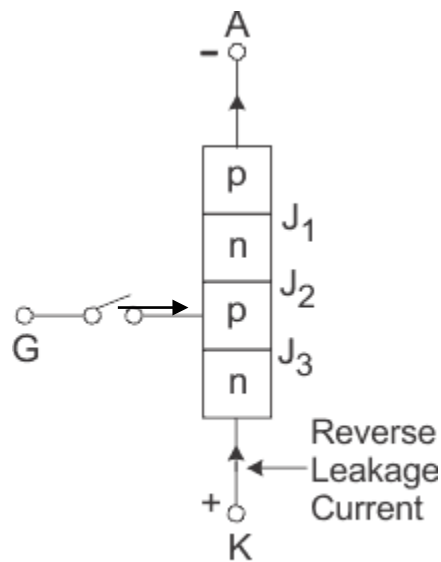


w/ more e^-
 \Rightarrow p type becomes N type

Thyristors

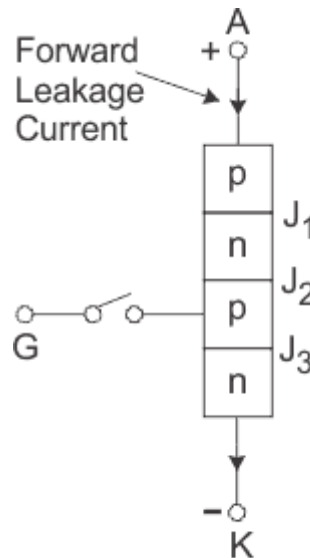


- Three modes of operation:
 - Reverse blocking state
 - Forward blocking state
 - Conduction or on state



Reverse Blocking Mode

Most of the voltage is held by J_1 .



Forward Biased Condition

Most of the voltage is held by J_2 .

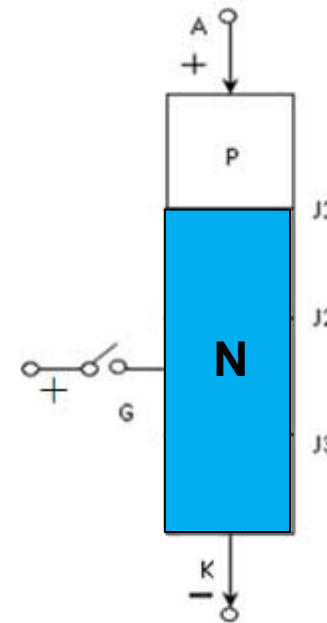


Fig 2: Forward Conduction

e^- will fill up the holes



w/ more e^-
 \Rightarrow p type becomes N type

Thyristors



- Without any external action, the thyristor cannot come back from the conducting to the blocking state.
- Two methods are generally applied:
 - Commutation of the current by polarity inversion.
 - Commutation of the current, supported by gate-assisted turn-off.

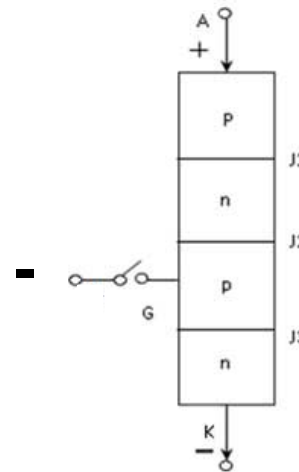
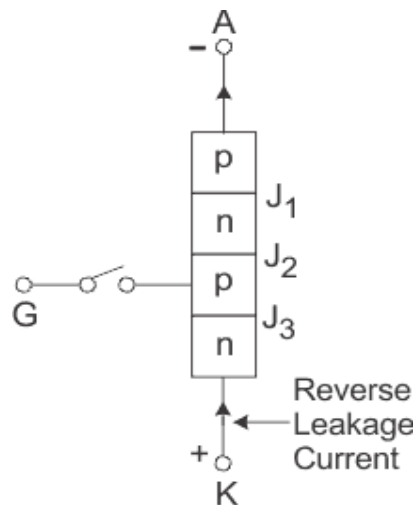
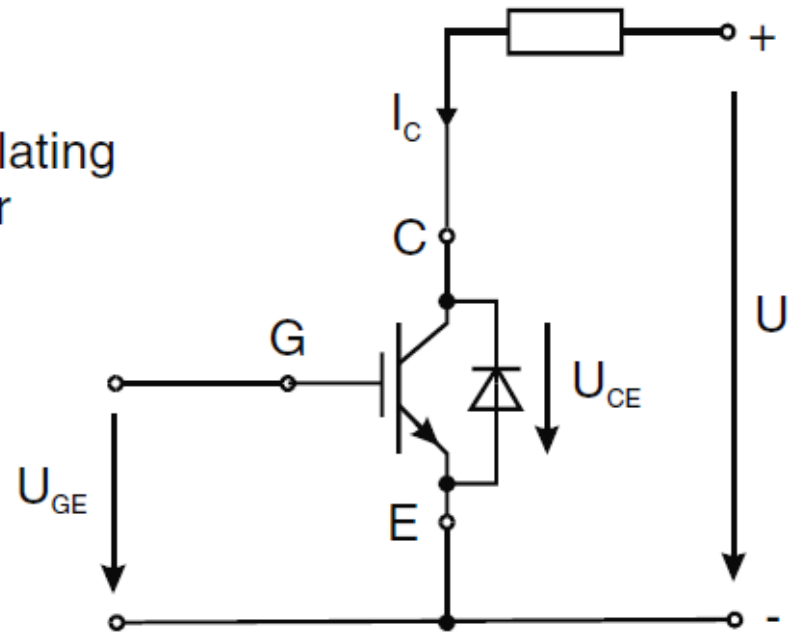
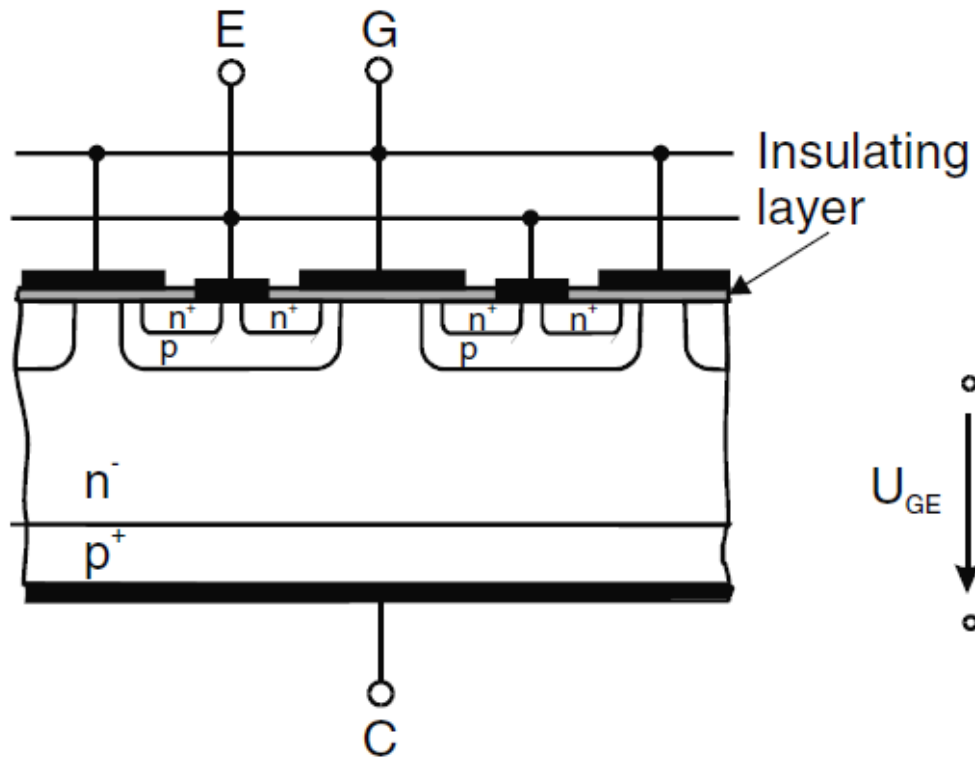


Fig 2: Forward Conduction

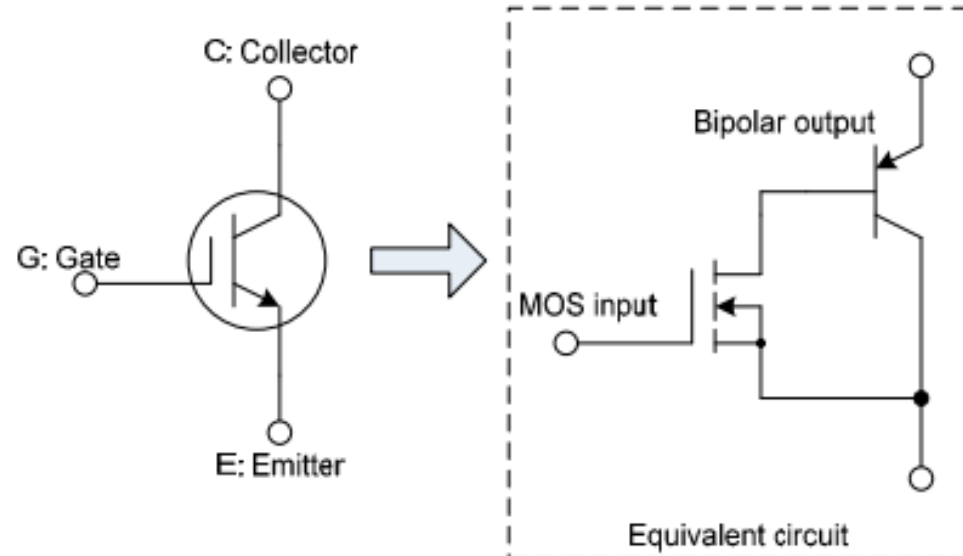
IGBT



IGBT



- **Advantage:**
 - **Bipolar transistors (BJT)** – low resistance in the switched-on state
 - **Field effect transistors (FET)** – loss-free gate control
- **Switch-on times:**
 - ~ several times 10 ns.
- It has a limited reverse-blocking capability => an external diode is sometimes used in parallel.
- **High-power IGBT:** blocking voltages $V \sim 4$ kV, on state $I \sim 3$ kA



Optically activated semiconductor switches



$$\nabla j_n = e(R_n - G_n) + e \frac{\partial n}{\partial t}$$

$$\nabla j_p = -e(R_p - G_p) - e \frac{\partial p}{\partial t}$$

$$eG_{av} = \alpha_n |j_n| + \alpha_p |j_p|$$

R_n: recombination rate.

G_n: generation rate.

- Electron and hole generation is caused either by optical excitation or by avalanche ionization at sufficiently high electric fields.

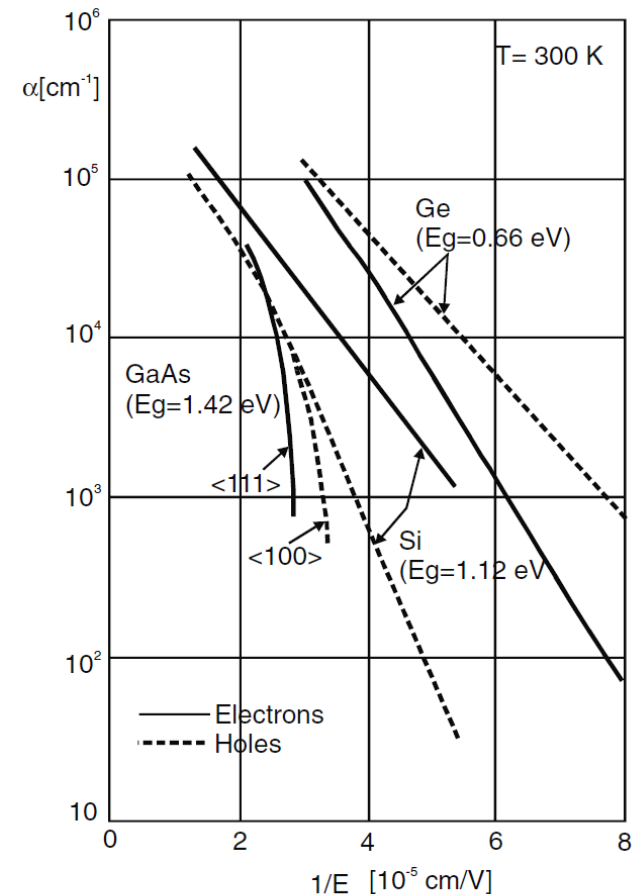
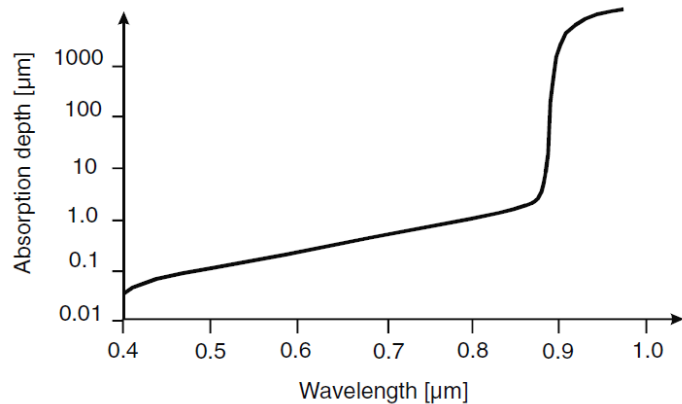


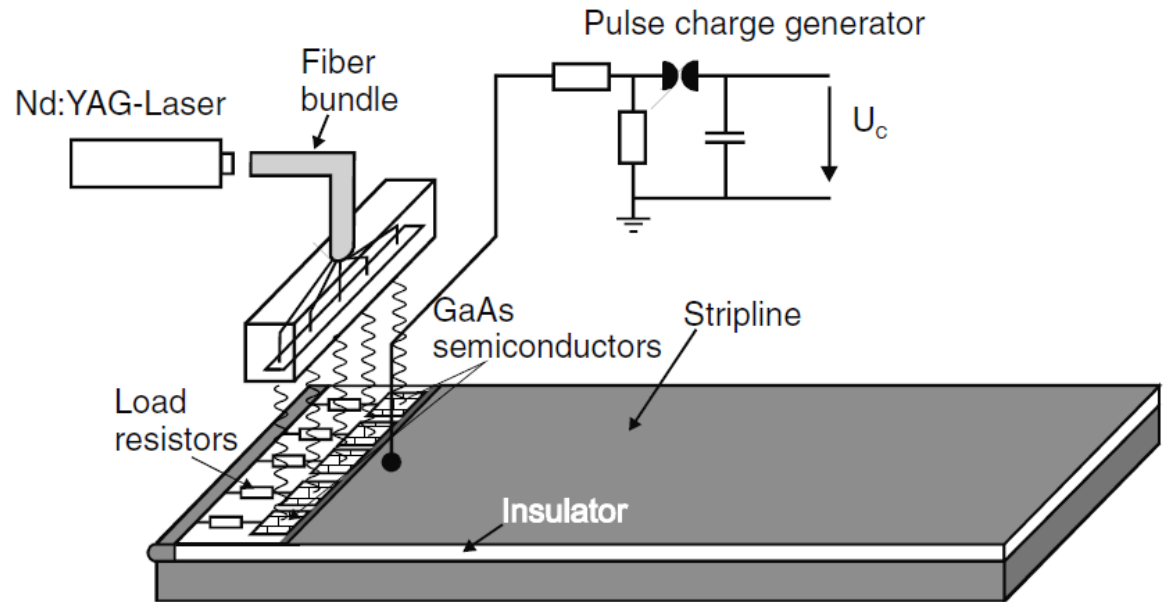
Fig. 4.31. Ionisation rate coefficients α_n and α_p

Optically activated semiconductor switches

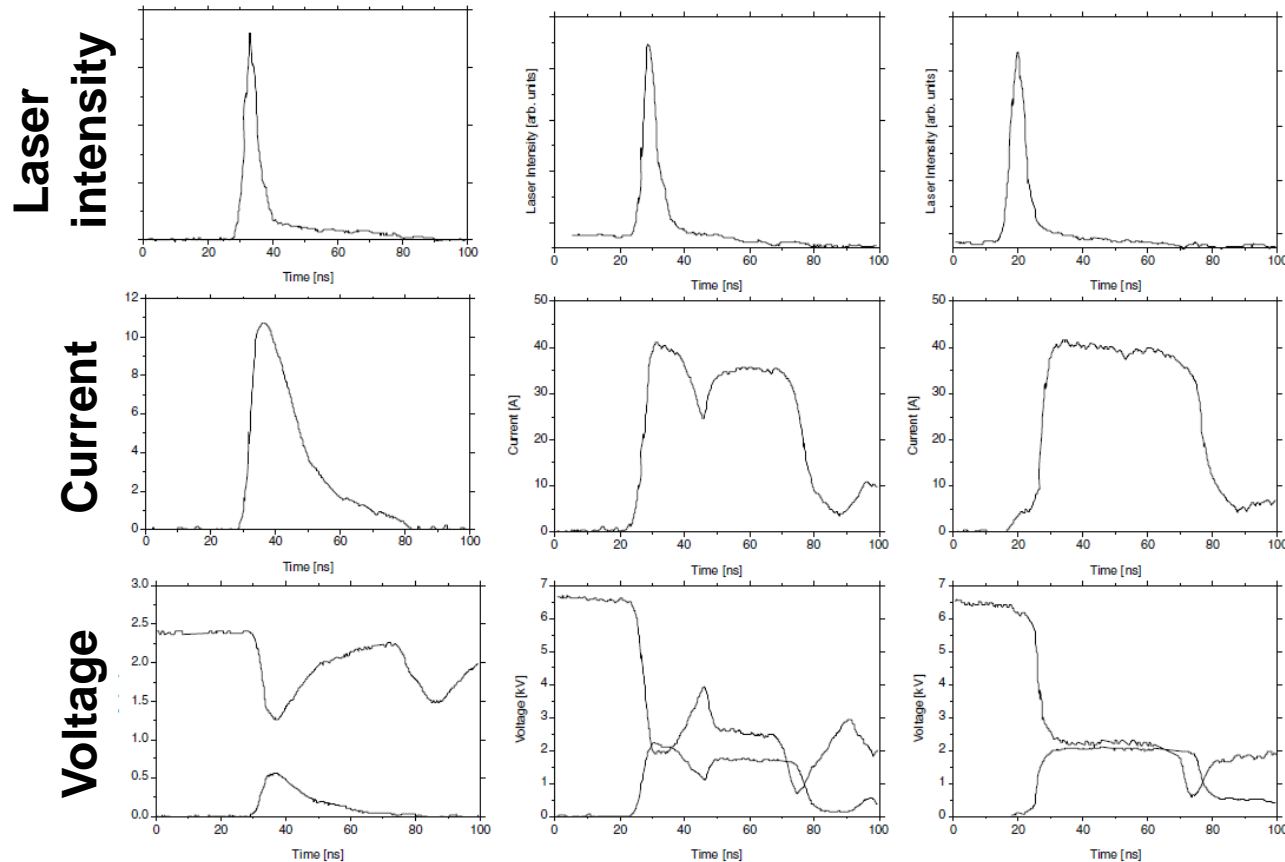


- The wavelength should be larger than 0.9 μm . Therefore a Nd:YAG laser, wavelength = 1.06 μm , is an appropriate light source.

Fig. 4.32. Optical absorption depth in GaAs as a function of wavelength

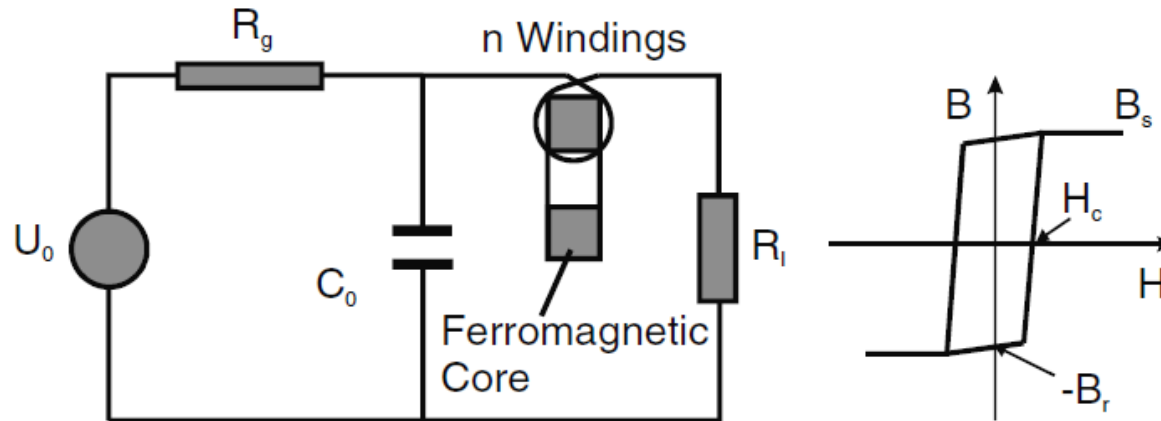


Optically activated semiconductor switches



- **Linear photoconducting regime:** the available number of charge carriers is determined only by the laser intensity.
- **Nonlinear regime:** the number of charge carriers is increased by collisional ionization and as in a gas switch increases exponentially.

Magnetic switches



- Relatively small losses and without wear.
- While the capacitor is being charged: the coil has a ferromagnetic core with high inductance at the beginning: $V=Ldi/dt \Rightarrow$ like an open switch.
- When saturation of the core is reached by the leakage current flowing through the coil $\Rightarrow L$ drops abruptly by a factor of $\mu \Rightarrow$ switch is closed.
- $\mu=B/H \rightarrow 0$ when saturated.
- The hysteresis loop should approximate a rectangular form, with an abrupt change of the permeability over several orders of magnitude when the saturation point is reached.

Summary



Type	Hold-off potential (kV)	Peak current (kA)	Cumulative charge (A s)	Repetition rate (Hz) [commutation time (ns)]	Lifetime (number of pulses)	Remarks
Spark gap	1-6000	10^{-3} -1000	0.1-50	1-10 [1-1000]	10^3 - 10^7	Lifetime is determined by electrode erosion
Thyratron	5-50	0.1-10	10^{-3}	1000 [5-100]	10^7 - 10^8	Applied in lasers and accelerators
Ignitron	> 10	> 100	2000	1 [1000]	10^5 - 10^6	Applied in lasers and accelerators
TVG	0.5-50	1-10	40	1 [10-100]	$> 10^4$	
Pseudo-spark	1-50	1-20	1	1-1000 [> 10]	10^6 - 10^8	Similar to Thyratron
Krytron	8	3	0.01-0.1	< 1000 [1-10]	10^7	Very short delay and commutation time
Magnetic Switch	1000	100-1000		10 [5-10000]	10^8 - 10^9	Cannot be triggered; one operating point only
Thyristor	< 5	< 5	10^{-2}	10 [> 1000]	10^8	Can be stacked; expensive; complex
IGBT	< 4	3		100	10^8	Can be switched off
GaAs photoactivated switch	< 20	1-10	$< 10^{-4}$	< 10 [1-10]	10^2 - 10^3	Needs intense light source